

## CURRENT-LIMITED, POWER-DISTRIBUTION SWITCHES

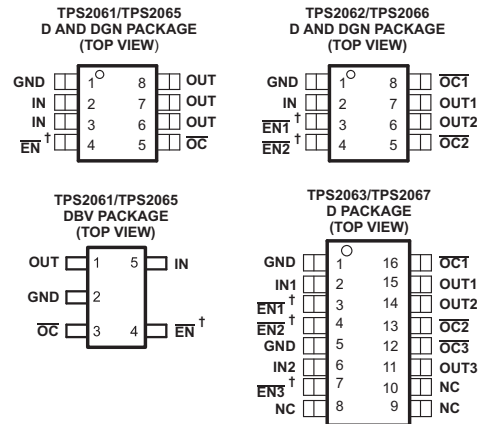
Check for Samples: [TPS2061](#) [TPS2062](#) [TPS2063](#) [TPS2065](#) [TPS2066](#) [TPS2067](#)

### FEATURES

- 70-mΩ High-Side MOSFET
- 1-A Continuous Current
- Thermal and Short-Circuit Protection
- Accurate Current Limit (1.1 A min, 1.9 A max)
- Operating Range: 2.7 V to 5.5 V
- 0.6-ms Typical Rise Time
- Undervoltage Lockout
- Deglitched Fault Report ( $\overline{OC}$ )
- No  $\overline{OC}$  Glitch During Power Up
- 1-μA Maximum Standby Supply Current
- Bidirectional Switch
- Ambient Temperature Range: -40°C to 85°C
- Built-in Soft-Start
- UL Listed - File No. E169910

### APPLICATIONS

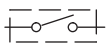
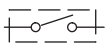
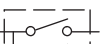
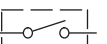
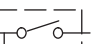
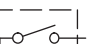
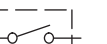
- Heavy Capacitive Loads
- Short-Circuit Protections



† All Enable Inputs Are Active High For TPS2065, TPS2066, and TPS2067

### DESCRIPTION

The TPS206x power-distribution switches are intended for applications where heavy capacitive loads and short-circuits are likely to be encountered. This device incorporates 70-mΩ N-channel MOSFET power switches for power-distribution systems that require multiple power switches in a single package. Each switch is controlled by a logic enable input. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external components and allows operation from supplies as low as 2.7 V.

GENERAL SWITCH CATALOG						
33 mΩ, Single	80 mΩ, Single	80 mΩ, Dual	80 mΩ, Dual	80 mΩ, Triple	80 mΩ, Quad	80 mΩ, Quad
						
TPS201xA 0.2 A to 2 A TPS202x 0.2 A to 2 A TPS203x 0.2 A to 2 A	TPS2014 600 mA TPS2015 1 A TPS2041B 500 mA TPS2051B 500 mA TPS2045A 250 mA TPS2049 100 mA TPS2055A 250 mA TPS2061 1 A TPS2065 1 A TPS2068 1.5 A TPS2069 1.5 A	TPS2042B 500 mA TPS2052B 500 mA TPS2046B 250 mA TPS2056 250 mA TPS2062 1 A TPS2066 1 A TPS2060 1.5 A TPS2064 1.5 A	TPS2080 500 mA TPS2081 500 mA TPS2082 500 mA TPS2090 250 mA TPS2091 250 mA TPS2092 250 mA	TPS2043B 500 mA TPS2053B 500 mA TPS2047B 250 mA TPS2057A 250 mA TPS2063 1 A TPS2067 1 A	TPS2044B 500 mA TPS2054B 500 mA TPS2048A 250 mA TPS2058 250 mA	TPS2085 500 mA TPS2086 500 mA TPS2087 500 mA TPS2095 250 mA TPS2096 250 mA TPS2097 250 mA



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## DESCRIPTION (CONTINUED)

When the output load exceeds the current-limit threshold or a short is present, the device limits the output current to a safe level by switching into a constant-current mode, pulling the overcurrent (OCx) logic output low. When continuous heavy overloads and short-circuits increase the power dissipation in the switch, causing the junction temperature to rise, a thermal protection circuit shuts off the switch to prevent damage. Recovery from a thermal shutdown is automatic once the device has cooled sufficiently. Internal circuitry ensures that the switch remains off until valid input voltage is present. This power-distribution switch is designed to set current limit at 1.5 A typically.

### AVAILABLE OPTION AND ORDERING INFORMATION

T <sub>A</sub>	ENABLE	RECOMMENDED MAXIMUM CONTINUOUS LOAD CURRENT	TYPICAL SHORT- CIRCUIT CURRENT LIMIT AT 25°C	NUMBER OF SWITCHES	PACKAGED DEVICES <sup>(1)</sup>		
					MSOP (DGN)	SOIC (D)	SOT23 (DBV) <sup>(2)</sup>
-40°C to 85°C	Active low	1 A	1.5 A	Single	TPS2061DGN	TPS2061D	-
	Active high				TPS2065DGN	TPS2065D	-
	Active low			Dual	TPS2062DGN	TPS2062D	-
	Active high				TPS2066DGN	TPS2066D	-
	Active low			Triple	-	TPS2063D	-
	Active high				-	TPS2067D	-
	Active low			Single	-	-	TPS2061DBV
	Active high				-	-	TPS2065DBV

(1) The package is available taped and reeled. Add an R suffix to device types (e.g., TPS2062DR).

(2) The printed circuit board layout is important for control of temperature rise when operated at high ambient temperatures.

### ORDERING INFORMATION

T <sub>A</sub>	SOIC(D) <sup>(1)</sup>	STATUS	MSOP (DGN) <sup>(1)</sup>	STATUS	SOT23 (DBV) <sup>(2)</sup>	STATUS
-40°C to 85°C	TPS2061DG4	Active	TPS2061DGNG4	Active	-	-
	TPS2062DG4	Active	TPS2062DGNG4	Active	-	-
	TPS2065DG4	Active	TPS2065DGNG4	Active	-	-
	TPS2066DG4	Active	TPS2066DGNG4	Active	-	-
	-	-	-	-	TPS2061DBV	Active
	-	-	-	-	TPS2065DBV	Active

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](http://www.ti.com).

(2) The printed circuit board layout is important for control of temperature rise when operated at high ambient temperatures.

## ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted<sup>(1)</sup>

		UNIT
Input voltage range, $V_{I(IN)}$ <sup>(2)</sup>		-0.3 V to 6 V
Output voltage range, $V_{O(OUT)}$ <sup>(2)</sup> , $V_{O(OUTx)}$		-0.3 V to 6 V
Input voltage range, $V_{I(EN)}$ , $V_{I(EN)}$ , $V_{I(ENx)}$ , $V_{I(ENx)}$		-0.3 V to 6 V
Voltage range, $V_{I(OC)}$ , $V_{I(OCx)}$		-0.3 V to 6 V
Continuous output current, $I_{O(OUT)}$ , $I_{O(OUTx)}$		Internally limited
Continuous total power dissipation		See Dissipation Rating Table
Operating virtual junction temperature range, $T_J$		-40°C to 150°C
Electrostatic discharge (ESD) protection	Human body model	2 kV
	Charge device model (CDM)	500 V

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to GND.

## DISSIPATING RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
D-8 <sup>(1)</sup>	585.82 mW	5.8582 mW/°C	322.20 mW	234.32 mW
DGN-8 <sup>(2)</sup>	1712.3 mW	17.123 mW/°C	941.78 mW	684.33 mW
D-16 <sup>(1)</sup>	898.47 mW	8.9847 mW/°C	494.15 mW	359.38 mW
DBV-5 <sup>(3)</sup>	285 mW	2.85 mW/°C	155 mW	114 mW
	704 mW	7.04 mW/°C	387 mW	281 mW

- (1) Power ratings are based on the low-k board (1 signal, 1 layer).
- (2) Power ratings are based on the high-k board (2 signal, 2 plane) with PowerPAD™ vias to the internal ground plane.
- (3) Lower ratings are for low-k printed circuit board layout (single -sided). Higher ratings are for enhanced high-k layout, (2 signal, 2 plane) with a 1mm<sup>2</sup> copper pad on pin 2 and 2 vias to the ground plane.

## RECOMMENDED OPERATING CONDITIONS

	MIN	MAX	UNIT
Input voltage, $V_{I(IN)}$	2.7	5.5	V
Input voltage, $V_{I(EN)}$ , $V_{I(EN)}$ , $V_{I(ENx)}$ , $V_{I(ENx)}$	0	5.5	V
Continuous output current, $I_{O(OUT)}$ , $I_{O(OUTx)}$	0	1	A
Operating virtual junction temperature, $T_J$	-40	125	°C

## ELECTRICAL CHARACTERISTICS

over recommended operating junction temperature range,  $V_{I(IN)} = 5.5$  V,  $I_O = 1$  A,  $V_{I(ENx)} = 0$  V, or  $V_{I(ENx)} = 5.5$  V (unless otherwise noted)

PARAMETER		TEST CONDITIONS <sup>(1)</sup>		MIN	TYP	MAX	UNIT
POWER SWITCH							
r <sub>DS(on)</sub>	Static drain-source on-state resistance, 5-V operation and 3.3-V operation	V <sub>I(IN)</sub> = 5 V or 3.3 V, I <sub>O</sub> = 1 A, -40°C ≤ T <sub>J</sub> ≤ 125°C			70	135	mΩ
	Static drain-source on-state resistance, 2.7-V operation	V <sub>I(IN)</sub> = 2.7 V, I <sub>O</sub> = 1 A, -40°C ≤ T <sub>J</sub> ≤ 125°C			75	150	mΩ
t <sub>r</sub>	Rise time, output	V <sub>I(IN)</sub> = 5.5 V	C <sub>L</sub> = 1 μF, R <sub>L</sub> = 5 Ω, T <sub>J</sub> = 25°C		0.6	1.5	ms
		V <sub>I(IN)</sub> = 2.7 V			0.4	1	
t <sub>f</sub>	Fall time, output	V <sub>I(IN)</sub> = 5.5 V			0.05	0.5	
		V <sub>I(IN)</sub> = 2.7 V			0.05	0.5	

- (1) Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

## ELECTRICAL CHARACTERISTICS (continued)

over recommended operating junction temperature range,  $V_{I(IN)} = 5.5\text{ V}$ ,  $I_O = 1\text{ A}$ ,  $V_{I(ENx)} = 0\text{ V}$ , or  $V_{I(ENx)} = 5.5\text{ V}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS <sup>(1)</sup>		MIN	TYP	MAX	UNIT
ENABLE INPUT $\overline{\text{EN}}$ OR EN							
$V_{IH}$	High-level input voltage	$2.7\text{ V} \leq V_{I(IN)} \leq 5.5\text{ V}$		2			V
$V_{IL}$	Low-level input voltage	$2.7\text{ V} \leq V_{I(IN)} \leq 5.5\text{ V}$				0.8	
$I_I$	Input current	$V_{I(\overline{\text{ENx}})} = 0\text{ V}$ or $5.5\text{ V}$ , $V_{I(\text{ENx})} = 0\text{ V}$ or $5.5\text{ V}$		-0.5		0.5	$\mu\text{A}$
$t_{on}$	Turnon time	$C_L = 100\text{ }\mu\text{F}$ , $R_L = 5\text{ }\Omega$				3	ms
$t_{off}$	Turnoff time	$C_L = 100\text{ }\mu\text{F}$ , $R_L = 5\text{ }\Omega$				10	
CURRENT LIMIT							
$I_{OS}$	Short-circuit output current	$V_{I(IN)} = 5\text{ V}$ , OUT connected to GND, device enabled into short-circuit	$T_J = 25^\circ\text{C}$	1.1	1.5	1.9	A
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	1.1	1.5	2.1	
$I_{OC\_TRIP}$	Overcurrent trip threshold	$V_{I(IN)} = 5\text{ V}$ , current ramp ( $\leq 100\text{ A/s}$ ) on OUT	TPS2061, TPS2062, TPS2065, TPS2066	1.6	2.3	2.7	A
			TPS2063, TPS2067	1.6	2.4	3.0	
SUPPLY CURRENT (TPS2061, TPS2065)							
Supply current, low-level output		No load on OUT, $V_{I(\overline{\text{ENx}})} = 5.5\text{ V}$ , or $V_{I(\text{ENx})} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	0.5	1	$\mu\text{A}$	
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	0.5	5		
Supply current, high-level output		No load on OUT, $V_{I(\overline{\text{ENx}})} = 0\text{ V}$ , or $V_{I(\text{ENx})} = 5.5\text{ V}$	$T_J = 25^\circ\text{C}$	43	60	$\mu\text{A}$	
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	43	70		
Leakage current		OUT connected to ground, $V_{I(\overline{\text{EN}})} = 5.5\text{ V}$ , or $V_{I(\text{EN})} = 0\text{ V}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	1		$\mu\text{A}$	
Reverse leakage current		$V_{I(OUTx)} = 5.5\text{ V}$ , IN = ground	$T_J = 25^\circ\text{C}$	0		$\mu\text{A}$	
SUPPLY CURRENT (TPS2062, TPS2066)							
Supply current, low-level output		No load on OUT, $V_{I(\overline{\text{ENx}})} = 5.5\text{ V}$ , or $V_{I(\text{ENx})} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	0.5	1	$\mu\text{A}$	
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	0.5	5		
Supply current, high-level output		No load on OUT, $V_{I(\overline{\text{ENx}})} = 0\text{ V}$ , or $V_{I(\text{ENx})} = 5.5\text{ V}$	$T_J = 25^\circ\text{C}$	50	70	$\mu\text{A}$	
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	50	90		
Leakage current		OUT connected to ground, $V_{I(\text{ENx})} = 5.5\text{ V}$ , or $V_{I(\overline{\text{ENx}})} = 0\text{ V}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	1		$\mu\text{A}$	
Reverse leakage current		$V_{I(OUTx)} = 5.5\text{ V}$ , IN = ground	$T_J = 25^\circ\text{C}$	0.2		$\mu\text{A}$	
SUPPLY CURRENT (TPS2063, TPS2067)							
Supply current, low-level output		No load on OUT, $V_{I(\overline{\text{ENx}})} = 0\text{ V}$	$T_J = 25^\circ\text{C}$	0.5	2	$\mu\text{A}$	
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	0.5	10		
Supply current, high-level output		No load on OUT, $V_{I(\overline{\text{ENx}})} = 5.5\text{ V}$	$T_J = 25^\circ\text{C}$	65	90	$\mu\text{A}$	
			$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	65	110		
Leakage current		OUT connected to ground, $V_{I(\overline{\text{ENx}})} = 5.5\text{ V}$ , or $V_{I(\text{ENx})} = 0\text{ V}$	$-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$	1		$\mu\text{A}$	
Reverse leakage current		$V_{I(OUTx)} = 5.5\text{ V}$ , INx = ground	$T_J = 25^\circ\text{C}$	0.2		$\mu\text{A}$	
UNDERVOLTAGE LOCKOUT							
Low-level input voltage, IN				2		2.5	V
Hysteresis, IN		$T_J = 25^\circ\text{C}$		75			mV
OVERCURRENT $\overline{\text{OC1}}$ and $\overline{\text{OC2}}$							
Output low voltage, $V_{OL(OCx)}$		$I_{O(\overline{\text{OCx}})} = 5\text{ mA}$				0.4	V
Off-state current		$V_{O(\overline{\text{OCx}})} = 5\text{ V}$ or $3.3\text{ V}$				1	$\mu\text{A}$
$\overline{\text{OC}}$ deglitch		$\overline{\text{OCx}}$ assertion or deassertion		4	8	15	ms
THERMAL SHUTDOWN <sup>(2)</sup>							
Thermal shutdown threshold				135			$^\circ\text{C}$
Recovery from thermal shutdown				125			$^\circ\text{C}$
Hysteresis					10		$^\circ\text{C}$

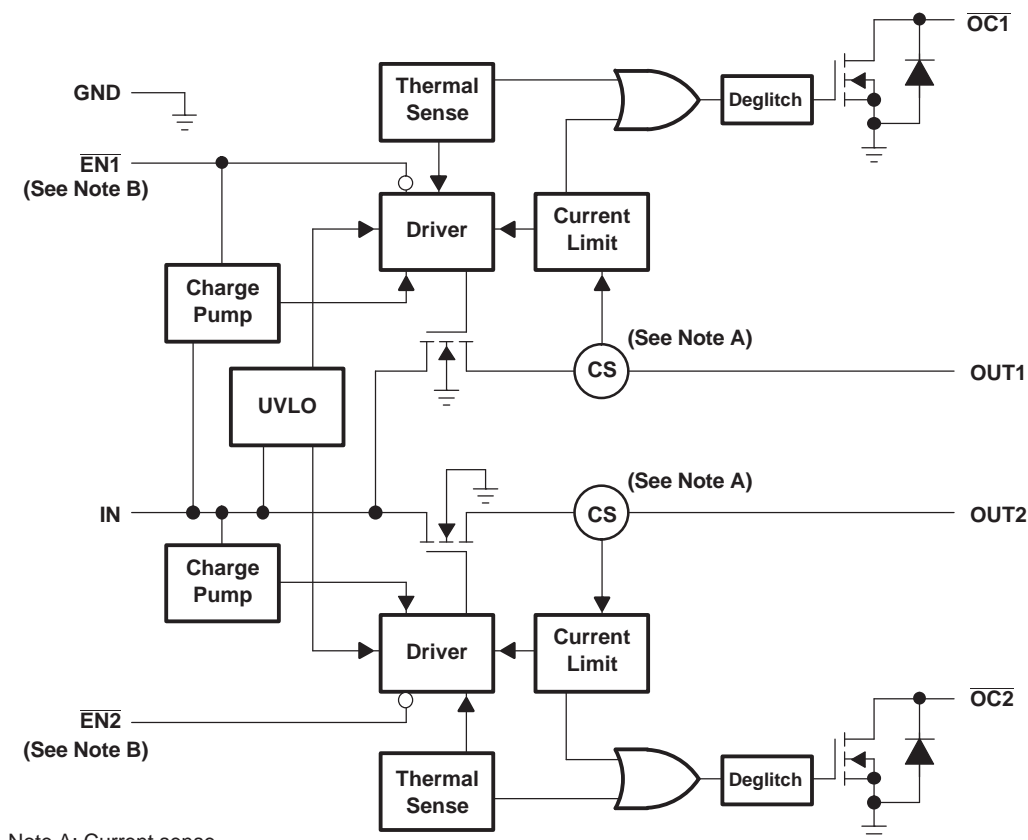
(2) The thermal shutdown only reacts under overcurrent conditions.



## Pin Functions (TPS2062 and TPS2066)

PINS			I/O	DESCRIPTION
NAME	NO.			
	TPS2062	TPS2066		
$\overline{\text{EN1}}$	3	-	I	Enable input, logic low turns on power switch IN-OUT1
$\overline{\text{EN2}}$	4	-	I	Enable input, logic low turns on power switch IN-OUT2
EN1	-	3	I	Enable input, logic high turns on power switch IN-OUT1
EN2	-	4	I	Enable input, logic high turns on power switch IN-OUT2
GND	1	1		Ground
IN	2	2	I	Input voltage
$\overline{\text{OC1}}$	8	8	O	Overcurrent, open-drain output, active low, IN-OUT1
$\overline{\text{OC2}}$	5	5	O	Overcurrent, open-drain output, active low, IN-OUT2
OUT1	7	7	O	Power-switch output, IN-OUT1
OUT2	6	6	O	Power-switch output, IN-OUT2
PowerPAD™	-	-		Internally connected to GND; used to heat-sink the part to the circuit board traces. Should be connected to GND pin.

## Functional Block Diagram



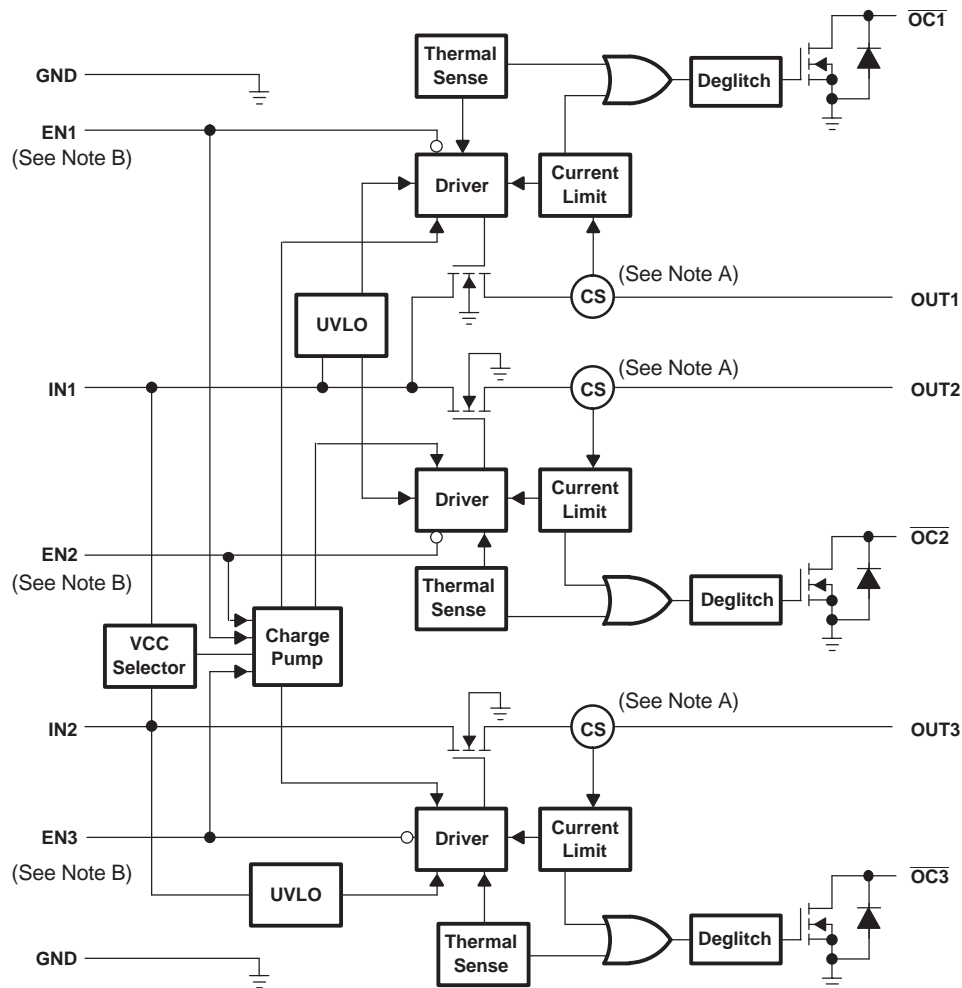
Note A: Current sense

Note B: Active low ( $\overline{\text{ENx}}$ ) for TPS2062. Active high (ENx) for TPS2066.

### Pin Functions (TPS2063 and TPS2067)

NAME	PINS		I/O	DESCRIPTION
	TPS2063	TPS2067		
$\overline{\text{EN1}}$	3	–	I	Enable input, logic low turns on power switch IN1-OUT1
$\overline{\text{EN2}}$	4	–	I	Enable input, logic low turns on power switch IN1-OUT2
$\overline{\text{EN3}}$	7	–	I	Enable input, logic low turns on power switch IN2-OUT3
EN1	–	3	I	Enable input, logic high turns on power switch IN1-OUT1
EN2	–	4	I	Enable input, logic high turns on power switch IN1-OUT2
EN3	–	7	I	Enable input, logic high turns on power switch IN2-OUT3
GND	1, 5	1, 5		Ground
IN1	2	2	I	Input voltage for OUT1 and OUT2
IN2	6	6	I	Input voltage for OUT3
NC	8, 9, 10	8, 9, 10		No connection
$\overline{\text{OC1}}$	16	16	O	Overcurrent, open-drain output, active low, IN1-OUT1
$\overline{\text{OC2}}$	13	13	O	Overcurrent, open-drain output, active low, IN1-OUT2
$\overline{\text{OC3}}$	12	12	O	Overcurrent, open-drain output, active low, IN2-OUT3
OUT1	15	15	O	Power-switch output, IN1-OUT1
OUT2	14	14	O	Power-switch output, IN1-OUT2
OUT3	11	11	O	Power-switch output, IN2-OUT3

## Functional Block Diagram

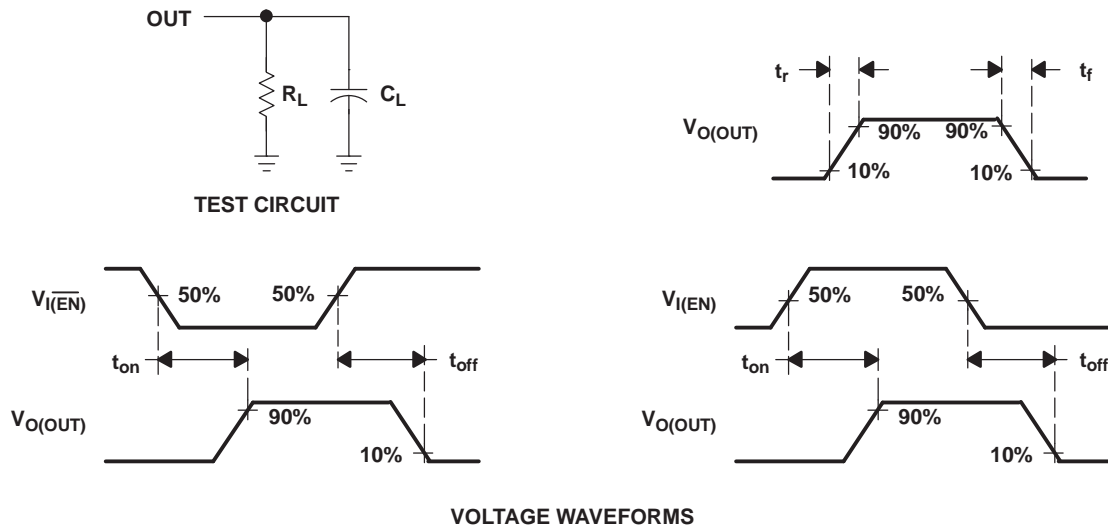


Note A: Current sense

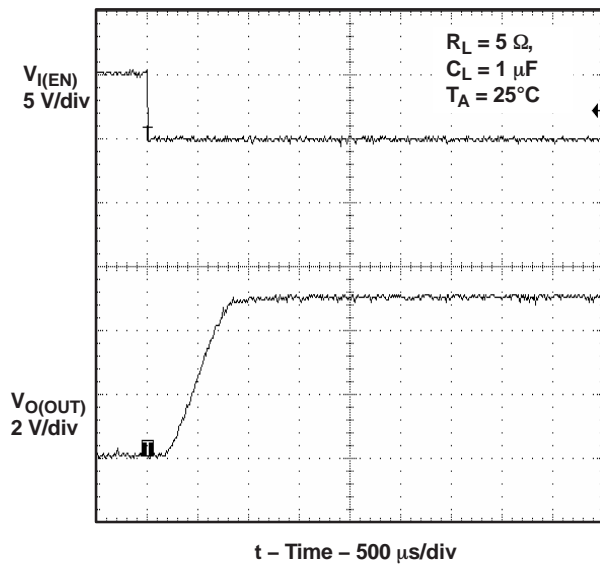
Note B: Active low ( $\overline{\text{ENx}}$ ) for TPS2063; Active high (ENx) for TPS2067



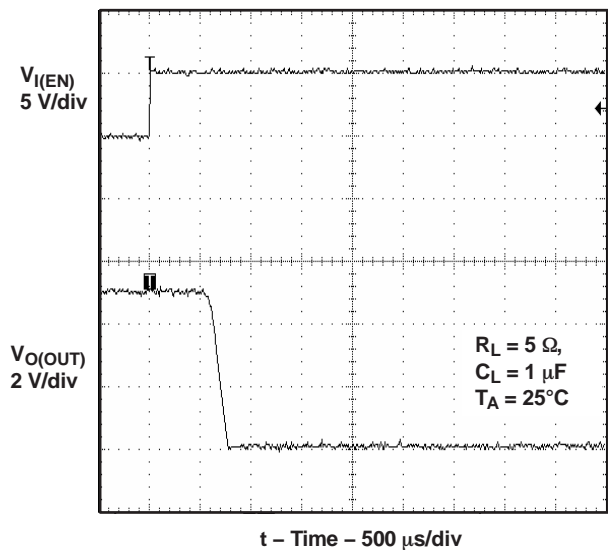
## PARAMETER MEASUREMENT INFORMATION



**Figure 1. Test Circuit and Voltage Waveforms**



**Figure 2. Turnon Delay and Rise Time With 1- $\mu\text{F}$  Load**



**Figure 3. Turnoff Delay and Fall Time With 1- $\mu\text{F}$  Load**

## PARAMETER MEASUREMENT INFORMATION (continued)

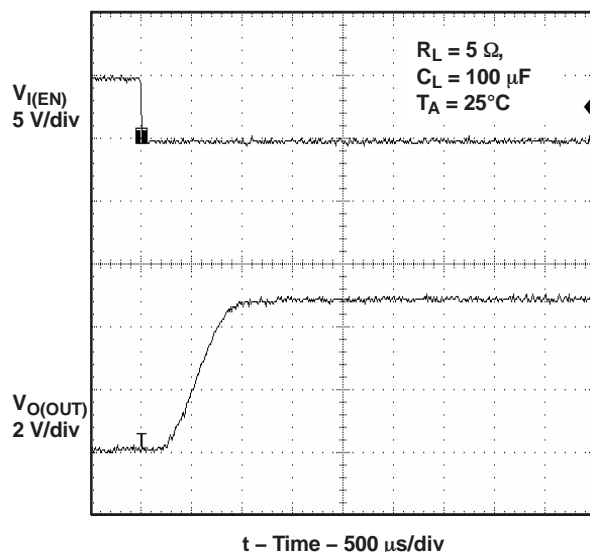


Figure 4. Turnon Delay and Rise Time With 100- $\mu F$  Load

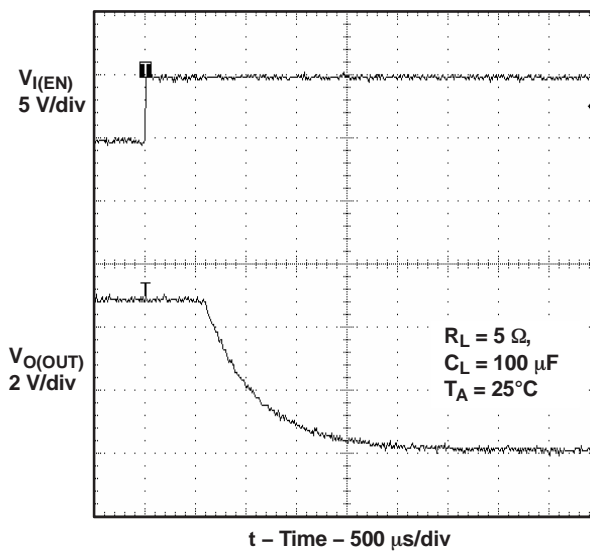


Figure 5. Turnoff Delay and Fall Time With 100- $\mu F$  Load

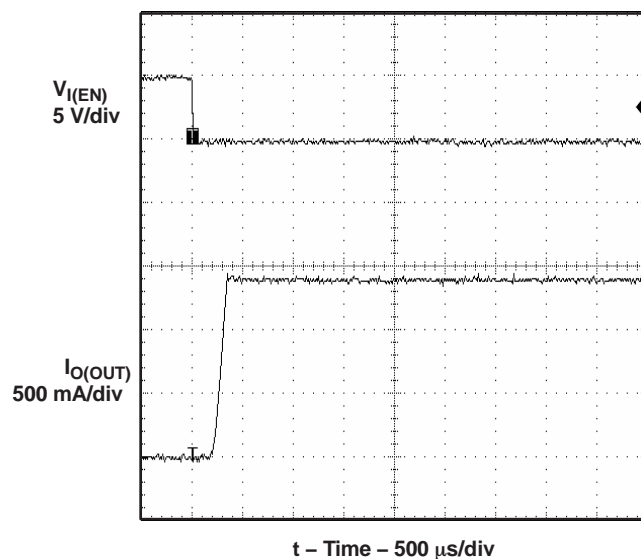


Figure 6. Short-Circuit Current, Device Enabled Into Short

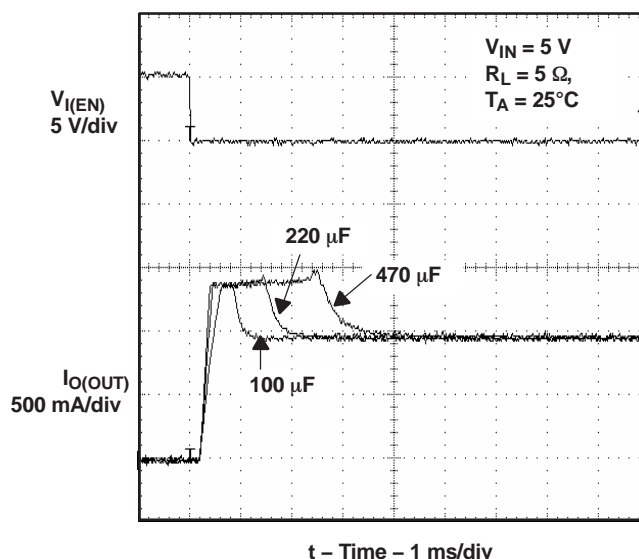


Figure 7. Inrush Current With Different Load Capacitance

## PARAMETER MEASUREMENT INFORMATION (continued)

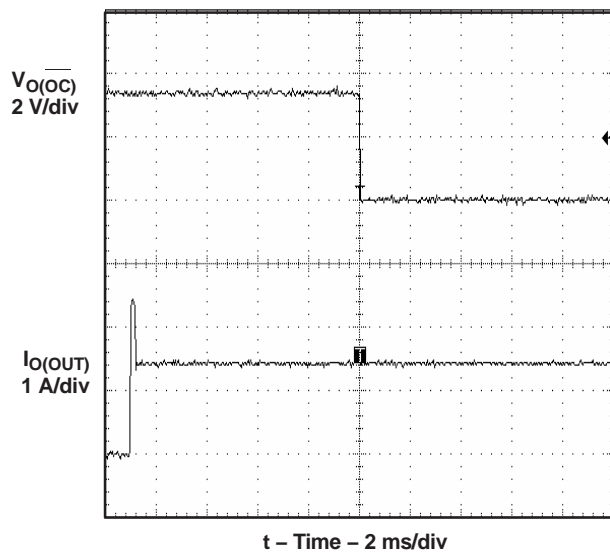


Figure 8. 2- $\Omega$  Load Connected to Enabled Device

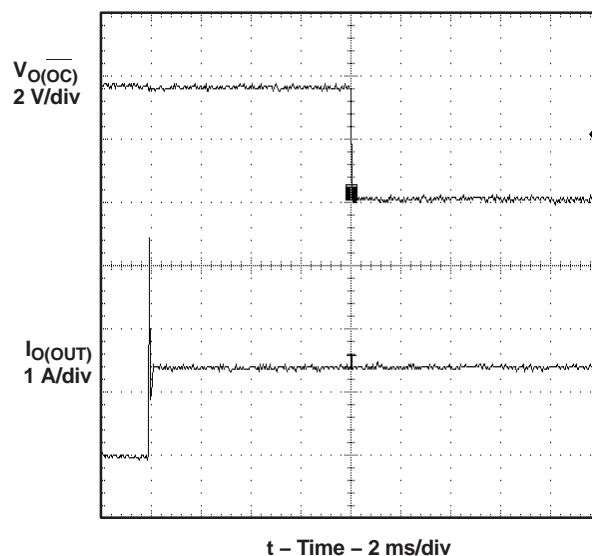


Figure 9. 1- $\Omega$  Load Connected to Enabled Device

## TYPICAL CHARACTERISTICS

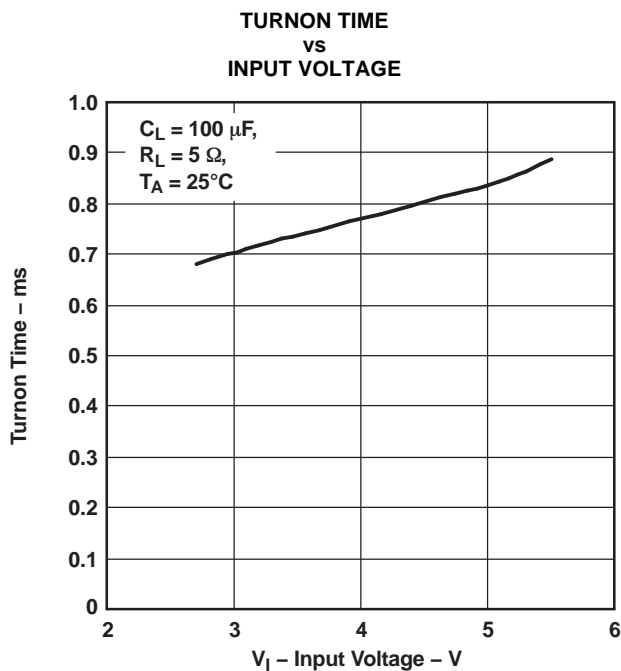


Figure 10.

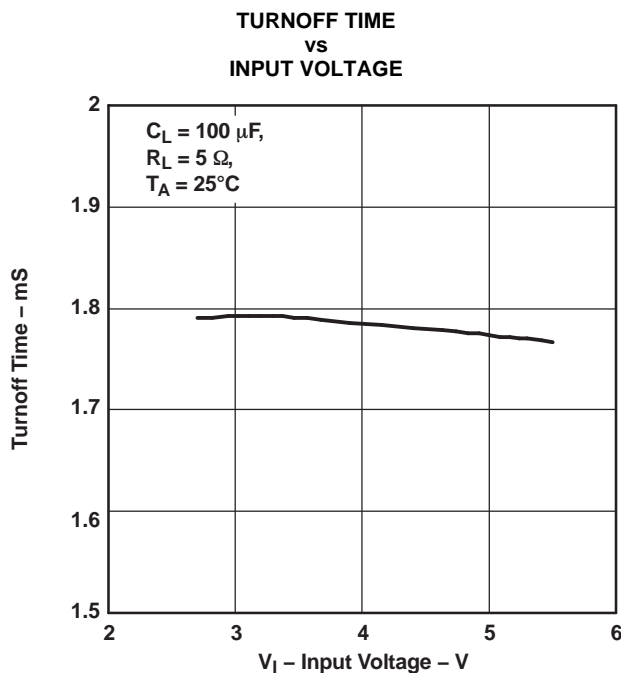


Figure 11.

## TYPICAL CHARACTERISTICS (continued)

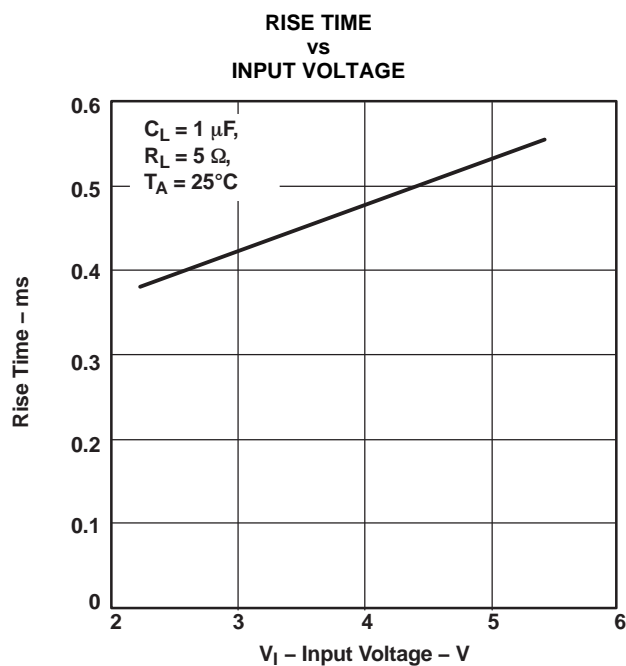


Figure 12.

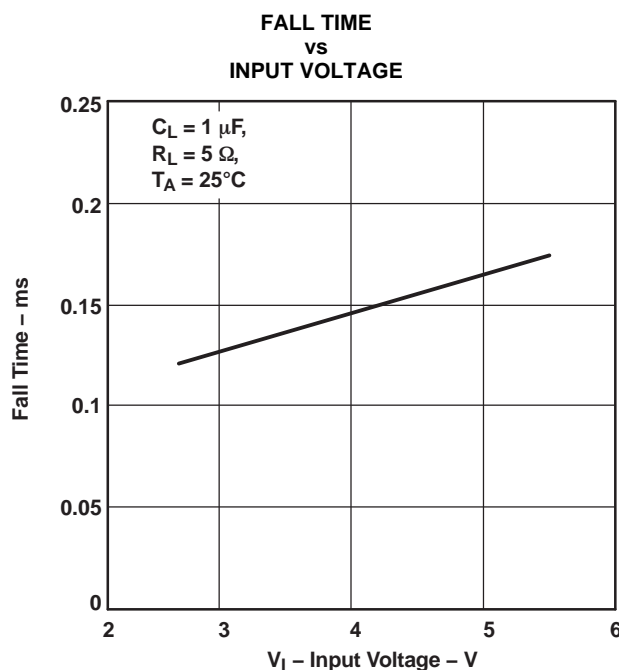


Figure 13.

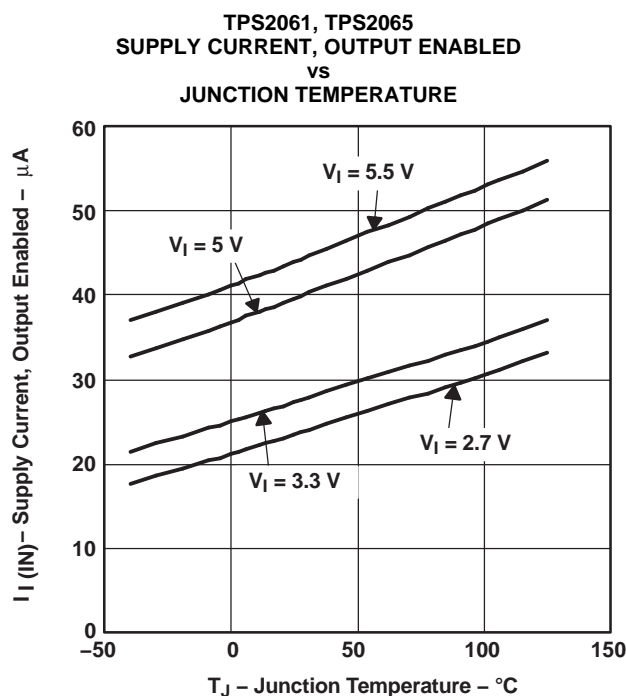


Figure 14.

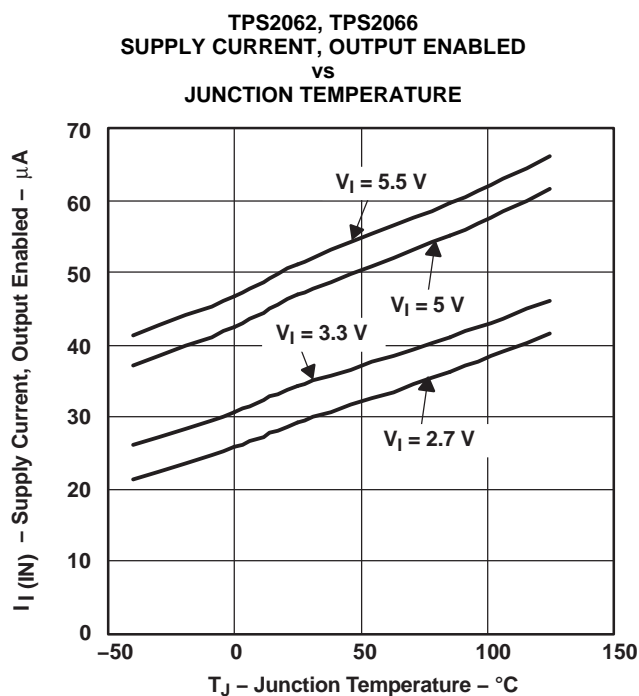


Figure 15.

## TYPICAL CHARACTERISTICS (continued)

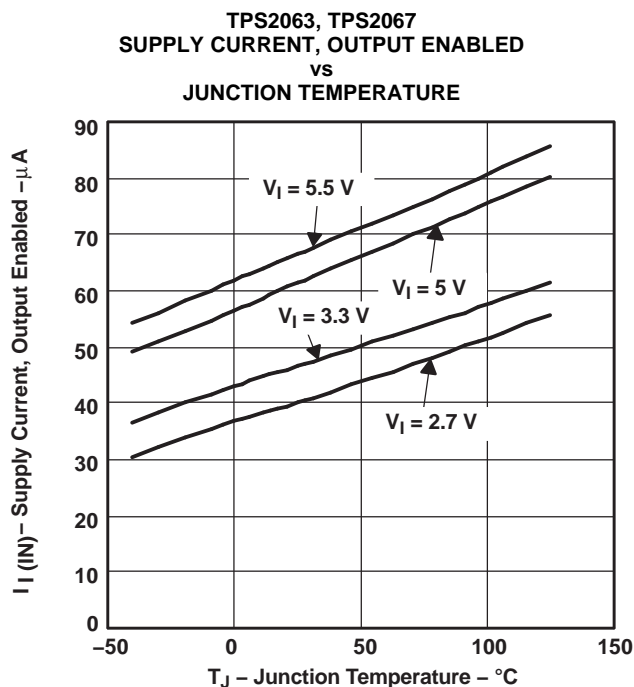


Figure 16.

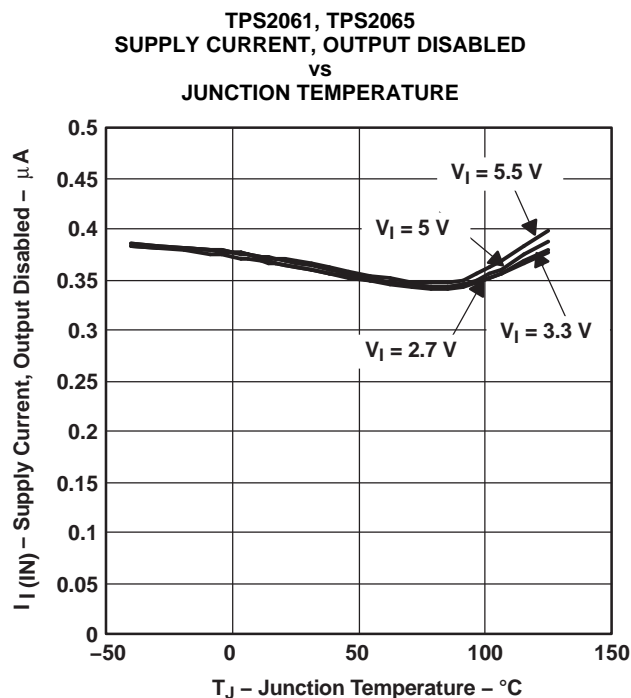


Figure 17.

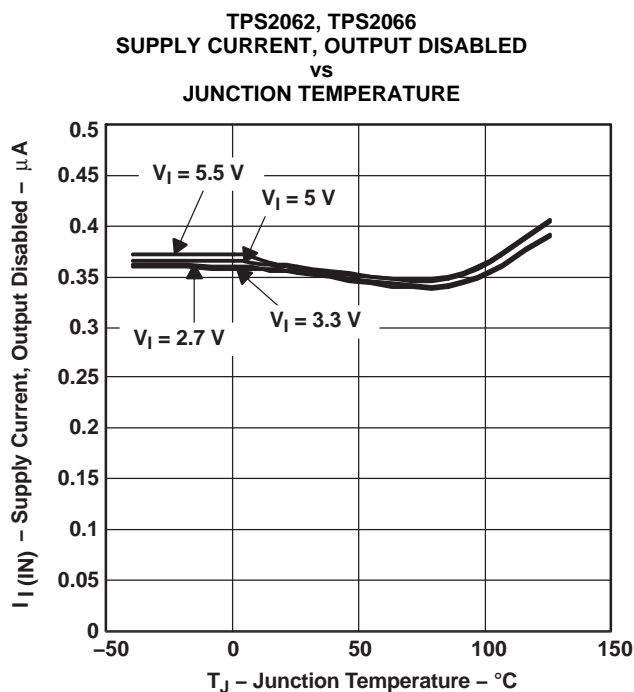


Figure 18.

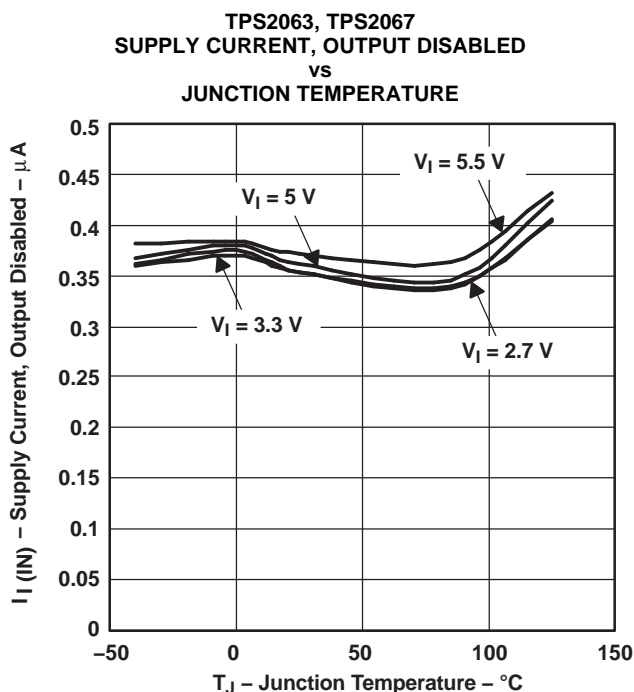


Figure 19.

## TYPICAL CHARACTERISTICS (continued)

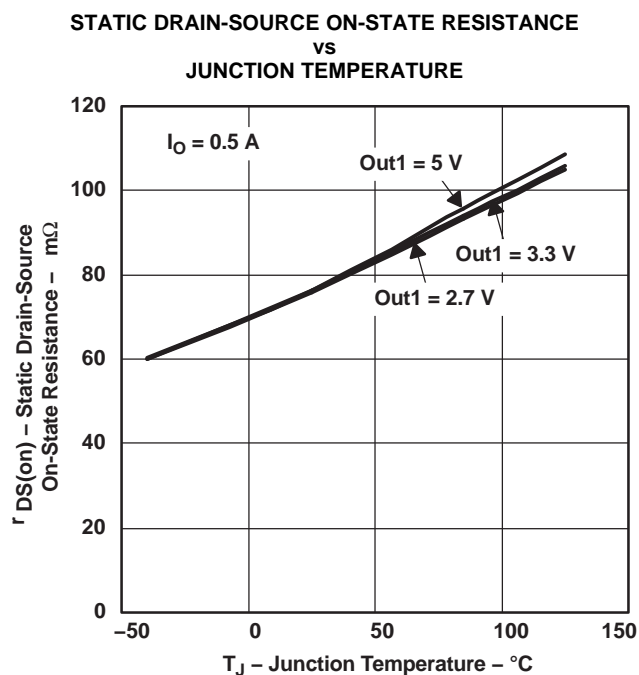


Figure 20.

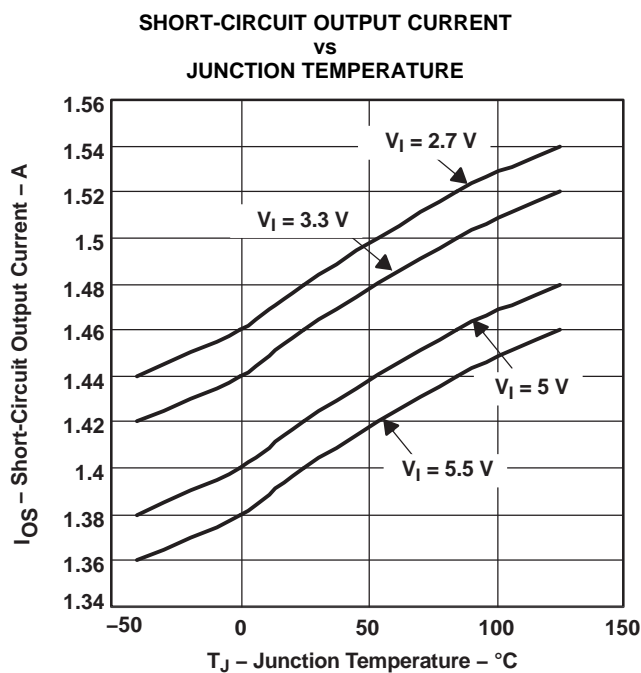


Figure 21.

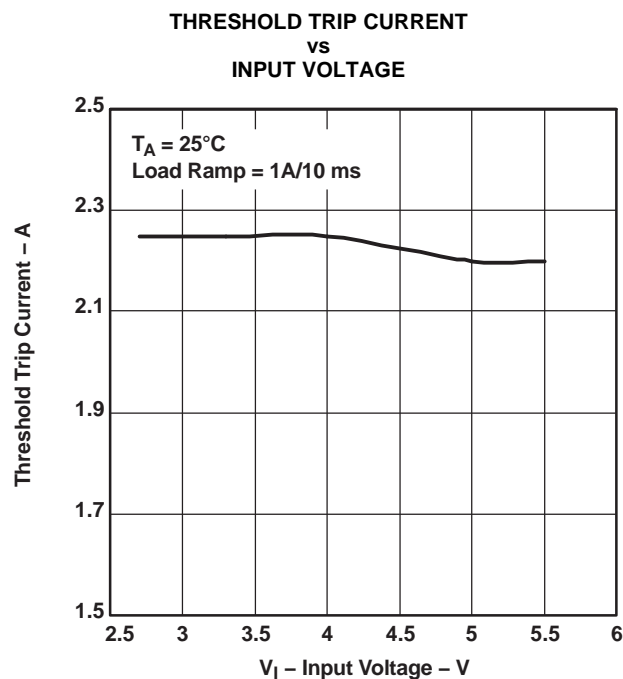


Figure 22.

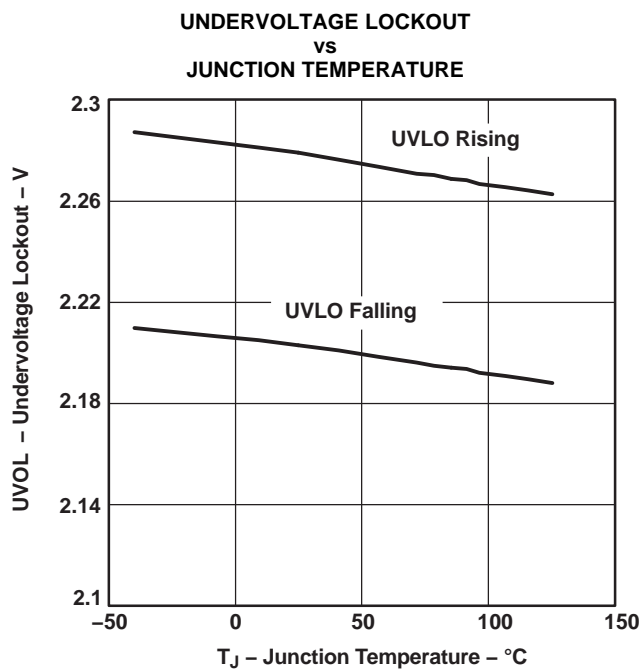
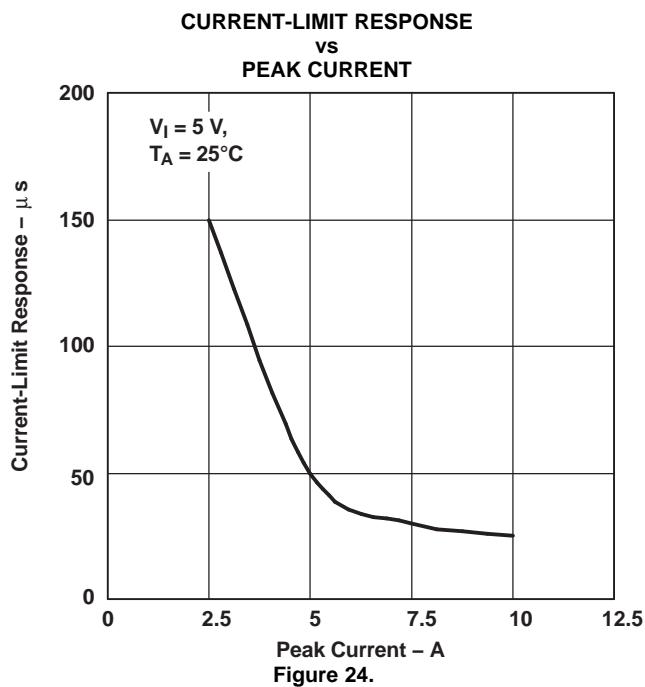


Figure 23.

## TYPICAL CHARACTERISTICS (continued)



## APPLICATION INFORMATION

### POWER-SUPPLY CONSIDERATIONS

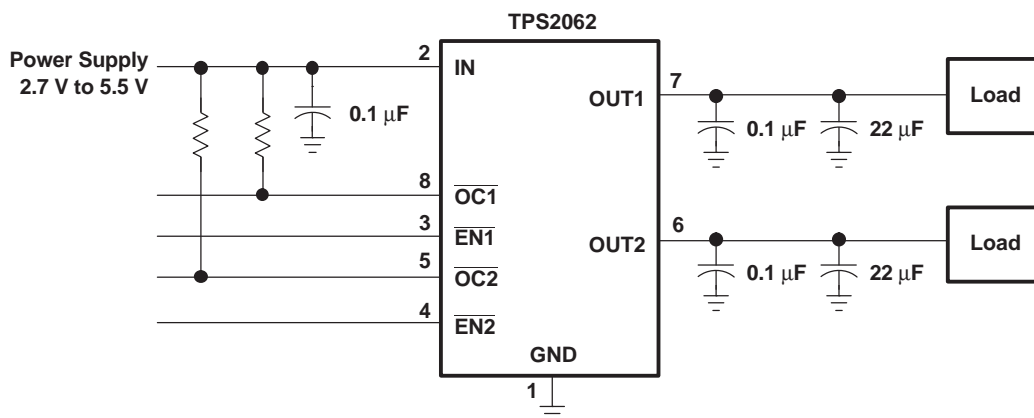


Figure 25. Typical Application

A 0.01-µF to 0.1-µF ceramic bypass capacitor between IN and GND, close to the device, is recommended. Placing a high-value electrolytic capacitor on the output pin(s) is recommended when the output load is heavy. This precaution reduces power-supply transients that may cause ringing on the input. Additionally, bypassing the output with a 0.01-µF to 0.1-µF ceramic capacitor improves the immunity of the device to short-circuit transients.

### OVERCURRENT

A sense FET is employed to check for overcurrent conditions. Unlike current-sense resistors, sense FETs do not increase the series resistance of the current path. When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Complete shutdown occurs only if the fault is present long enough to activate thermal limiting.

Three possible overload conditions can occur. In the first condition, the output has been shorted before the device is enabled or before  $V_{I(IN)}$  has been applied (see Figure 15). The TPS206x senses the short and immediately switches into a constant-current output.

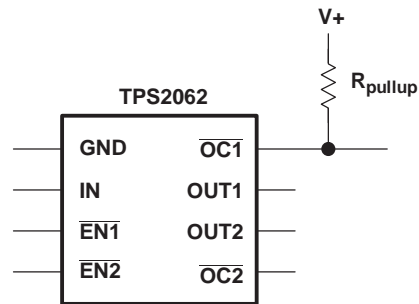
In the second condition, a short or an overload occurs while the device is enabled. At the instant the overload occurs, high currents may flow for a short period of time before the current-limit circuit can react. After the current-limit circuit has tripped (reached the overcurrent trip threshold), the device switches into constant-current mode.

In the third condition, the load has been gradually increased beyond the recommended operating current. The current is permitted to rise until the current-limit threshold is reached or until the thermal limit of the device is exceeded (see Figure 18). The TPS206x is capable of delivering current up to the current-limit threshold without damaging the device. Once the threshold has been reached, the device switches into its constant-current mode.

### OC RESPONSE

The  $\overline{OCx}$  open-drain output is asserted (active low) when an overcurrent or overtemperature shutdown condition is encountered after a 10-ms deglitch timeout. The output remains asserted until the overcurrent or overtemperature condition is removed. Connecting a heavy capacitive load to an enabled device can cause a momentary overcurrent condition; however, no false reporting on  $\overline{OCx}$  occurs due to the 10-ms deglitch circuit. The TPS206x is designed to eliminate false overcurrent reporting. The internal overcurrent deglitch eliminates the need for external components to remove unwanted pulses.  $\overline{OCx}$  is not deglitched when the switch is turned off due to an overtemperature shutdown.





**Figure 26. Typical Circuit for the  $\overline{OC}$  Pin**

## POWER DISSIPATION AND JUNCTION TEMPERATURE

The low on-resistance on the N-channel MOSFET allows the small surface-mount packages to pass large currents. The thermal resistances of these packages are high compared to those of power packages; it is good design practice to check power dissipation and junction temperature. Begin by determining the  $r_{DS(on)}$  of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read  $r_{DS(on)}$  from [Figure 20](#). Using this value, the power dissipation per switch can be calculated by:

- $P_D = r_{DS(on)} \times I^2$

Multiply this number by the number of switches being used. This step renders the total power dissipation from the N-channel MOSFETs.

The thermal resistance,  $R_{\theta JA} = 1 / (\text{DERATING FACTOR})$ , where DERATING FACTOR is obtained from the Dissipation Ratings Table. Thermal resistance is a strong function of the printed circuit board construction, and the copper trace area connecting the integrated circuit.

Finally, calculate the junction temperature:

- $T_J = P_D \times R_{\theta JA} + T_A$

Where:

- $T_A$  = Ambient temperature °C
- $R_{\theta JA}$  = Thermal resistance
- $P_D$  = Total power dissipation based on number of switches being used.

Compare the calculated junction temperature with the initial estimate. If they do not agree within a few degrees, repeat the calculation, using the calculated value as the new estimate. Two or three iterations are generally sufficient to get a reasonable answer.

## THERMAL PROTECTION

Thermal protection prevents damage to the IC when heavy-overload or short-circuit faults are present for extended periods of time. The TPS206x implements a thermal sensing to monitor the operating junction temperature of the power distribution switch. In an overcurrent or short-circuit condition, the junction temperature rises due to excessive power dissipation. Once the die temperature rises above a minimum of 135°C due to overcurrent conditions, the internal thermal sense circuitry turns the power switch off, thus preventing the power switch from damage. Hysteresis is built into the thermal sense circuit, and after the device has cooled approximately 10°C, the switch turns back on. The switch continues to cycle in this manner until the load fault or input power is removed. The OCx open-drain output is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

## **UNDERVOLTAGE LOCKOUT (UVLO)**

An undervoltage lockout ensures that the power switch is in the off state at power up. Whenever the input voltage falls below approximately 2 V, the power switch is quickly turned off. This facilitates the design of hot-insertion systems where it is not possible to turn off the power switch before input power is removed. The UVLO also keeps the switch from being turned on until the power supply has reached at least 2 V, even if the switch is enabled. On reinsertion, the power switch is turned on, with a controlled rise time to reduce EMI and voltage overshoots.

## **UNIVERSAL SERIAL BUS (USB) APPLICATIONS**

The universal serial bus (USB) interface is a 12-Mb/s, or 1.5-Mb/s, multiplexed serial bus designed for low-to-medium bandwidth PC peripherals (e.g., keyboards, printers, scanners, and mice). The four-wire USB interface is conceived for dynamic attach-detach (hot plug-unplug) of peripherals. Two lines are provided for differential data, and two lines are provided for 5-V power distribution.

USB data is a 3.3-V level signal, but power is distributed at 5 V to allow for voltage drops in cases where power is distributed through more than one hub across long cables. Each function must provide its own regulated 3.3 V from the 5-V input or its own internal power supply.

The USB specification defines the following five classes of devices, each differentiated by power-consumption requirements:

- Hosts/self-powered hubs (SPH)
- Bus-powered hubs (BPH)
- Low-power, bus-powered functions
- High-power, bus-powered functions
- Self-powered functions

SPHs and BPHs distribute data and power to downstream functions. The TPS206x has higher current capability than required by one USB port; so, it can be used on the host side and supplies power to multiple downstream ports or functions.

## **HOST/SELF-POWERED AND BUS-POWERED HUBS**

Hosts and SPHs have a local power supply that powers the embedded functions and the downstream ports (see [Figure 27](#)). This power supply must provide from 5.25 V to 4.75 V to the board side of the downstream connection under full-load and no-load conditions. Hosts and SPHs are required to have current-limit protection and must report overcurrent conditions to the USB controller. Typical SPHs are desktop PCs, monitors, printers, and stand-alone hubs.

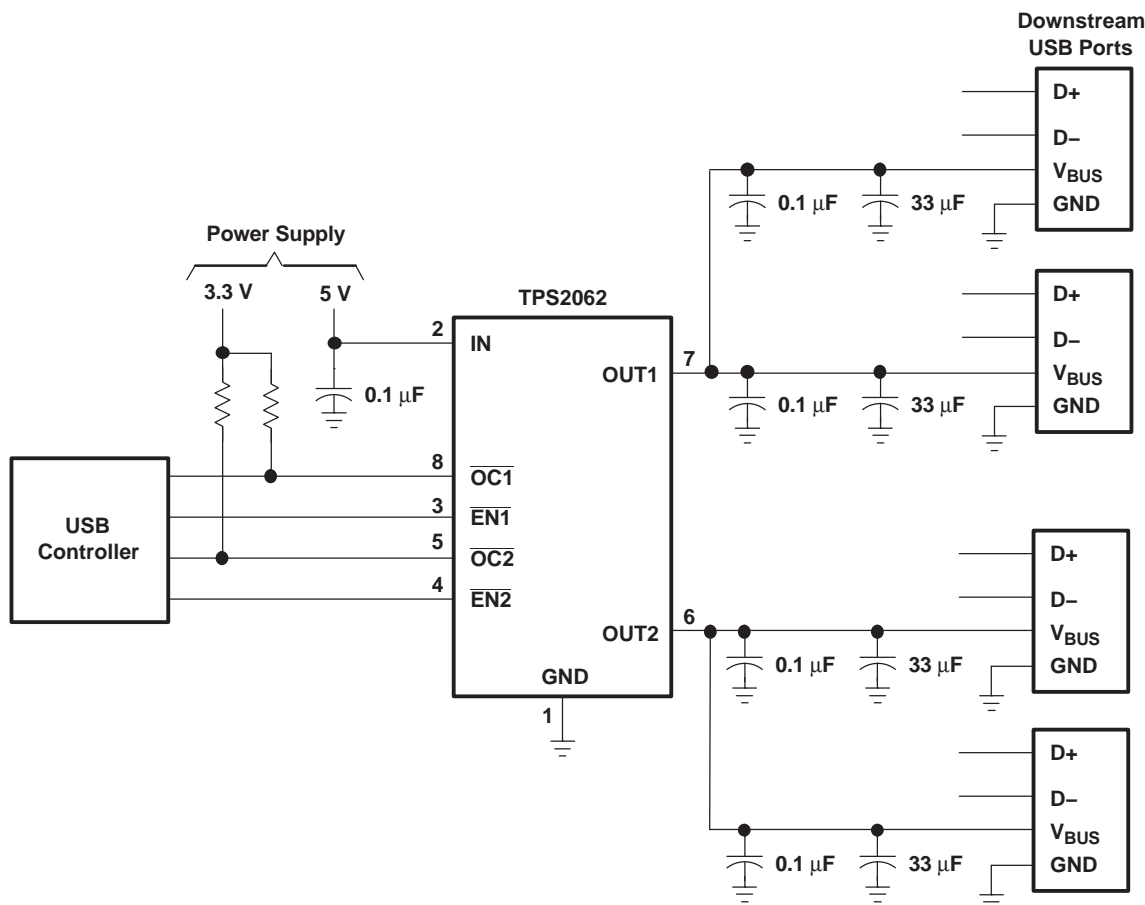


Figure 27. Typical Four-Port USB Host / Self-Powered Hub

BPHs obtain all power from upstream ports and often contain an embedded function. The hubs are required to power up with less than one unit load. The BPH usually has one embedded function, and power is always available to the controller of the hub. If the embedded function and hub require more than 100 mA on power up, the power to the embedded function may need to be kept off until enumeration is completed. This can be accomplished by removing power or by shutting off the clock to the embedded function. Power switching the embedded function is not necessary if the aggregate power draw for the function and controller is less than one unit load. The total current drawn by the bus-powered device is the sum of the current to the controller, the embedded function, and the downstream ports, and it is limited to 500 mA from an upstream port.

## LOW-POWER BUS-POWERED AND HIGH-POWER BUS-POWERED FUNCTIONS

Both low-power and high-power bus-powered functions obtain all power from upstream ports; low-power functions always draw less than 100 mA; high-power functions must draw less than 100 mA at power up and can draw up to 500 mA after enumeration. If the load of the function is more than the parallel combination of 44  $\Omega$  and 10  $\mu\text{F}$  at power up, the device must implement inrush current limiting (see Figure 28). With TPS206x, the internal functions could draw more than 500 mA, which fits the needs of some applications such as motor driving circuits.

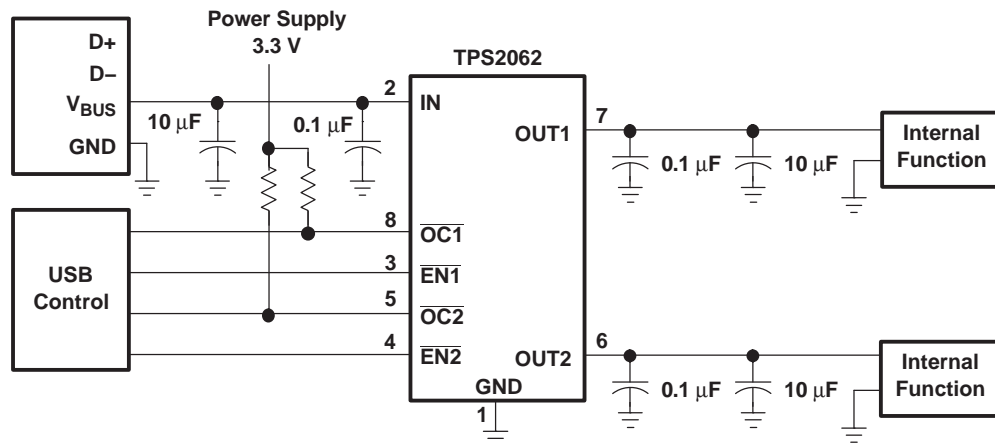


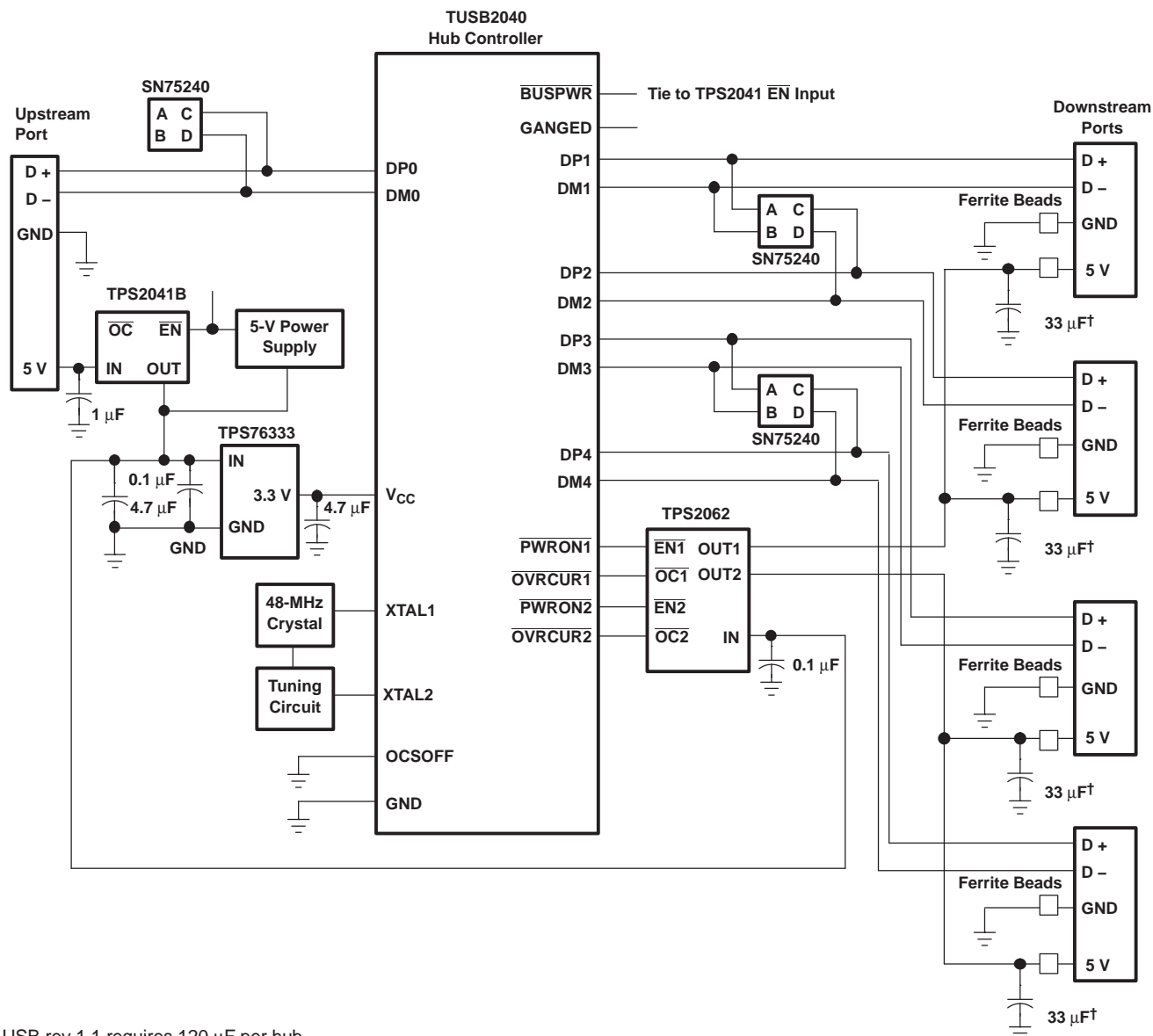
Figure 28. High-Power Bus-Powered Function

## USB POWER-DISTRIBUTION REQUIREMENTS

USB can be implemented in several ways, and, regardless of the type of USB device being developed, several power-distribution features must be implemented.

- Hosts/SPHs must:
  - Current-limit downstream ports
  - Report overcurrent conditions on USB  $V_{BUS}$
- BPHs must:
  - Enable/disable power to downstream ports
  - Power up at <100 mA
  - Limit inrush current (<44  $\Omega$  and 10  $\mu$ F)
- Functions must:
  - Limit inrush currents
  - Power up at <100 mA

The feature set of the TPS206x allows them to meet each of these requirements. The integrated current-limiting and overcurrent reporting is required by hosts and self-powered hubs. The logic-level enable and controlled rise times meet the need of both input and output ports on bus-powered hubs, as well as the input ports for bus-powered functions (see [Figure 29](#)).



† USB rev 1.1 requires 120  $\mu$ F per hub.

Figure 29. Hybrid Self / Bus-Powered Hub Implementation

## GENERIC HOT-PLUG APPLICATIONS

In many applications it may be necessary to remove modules or pc boards while the main unit is still operating. These are considered hot-plug applications. Such implementations require the control of current surges seen by the main power supply and the card being inserted. The most effective way to control these surges is to limit and slowly ramp the current and voltage being applied to the card, similar to the way in which a power supply normally turns on. Due to the controlled rise times and fall times of the TPS206x, these devices can be used to provide a softer start-up to devices being hot-plugged into a powered system. The UVLO feature of the TPS206x also ensures that the switch is off after the card has been removed, and that the switch is off during the next insertion. The UVLO feature insures a soft start with a controlled rise time for every insertion of the card or module.

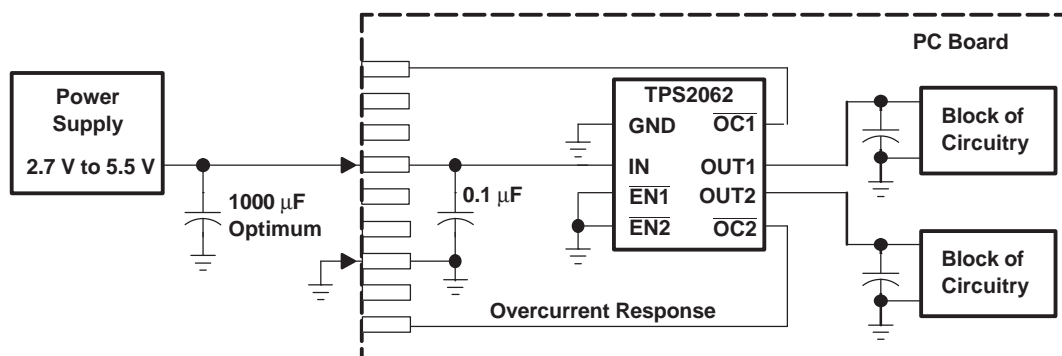


Figure 30. Typical Hot-Plug Implementation

By placing the TPS206x between the  $V_{CC}$  input and the rest of the circuitry, the input power reaches these devices first after insertion. The typical rise time of the switch is approximately 1 ms, providing a slow voltage ramp at the output of the device. This implementation controls system surge currents and provides a hot-plugging mechanism for any device.

## DETAILED DESCRIPTION

### Power Switch

The power switch is an N-channel MOSFET with a low on-state resistance. Configured as a high-side switch, the power switch prevents current flow from OUT to IN and IN to OUT when disabled. The power switch supplies a minimum current of 1 A.

### Charge Pump

An internal charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.7 V and requires little supply current.

### Driver

The driver controls the gate voltage of the power switch. To limit large current surges and reduce the associated electromagnetic interference (EMI) produced, the driver incorporates circuitry that controls the rise times and fall times of the output voltage.

### Enable ( $\overline{ENx}$ or $ENx$ )

The logic enable disables the power switch and the bias for the charge pump, driver, and other circuitry to reduce the supply current. The supply current is reduced to less than 1  $\mu A$  when a logic high is present on  $\overline{ENx}$ , or when a logic low is present on  $ENx$ . A logic zero input on  $\overline{ENx}$ , or a logic high input on  $ENx$  restores bias to the drive and control circuits and turns the switch on. The enable input is compatible with both TTL and CMOS logic levels.

### Overcurrent ( $\overline{OCx}$ )

The  $\overline{OCx}$  open-drain output is asserted (active low) when an overcurrent or overtemperature condition is encountered. The output remains asserted until the overcurrent or overtemperature condition is removed. A 10-ms deglitch circuit prevents the  $\overline{OCx}$  signal from oscillation or false triggering. If an overtemperature shutdown occurs, the  $\overline{OCx}$  is asserted instantaneously.

## Current Sense

A sense FET monitors the current supplied to the load. The sense FET measures current more efficiently than conventional resistance methods. When an overload or short circuit is encountered, the current-sense circuitry sends a control signal to the driver. The driver in turn reduces the gate voltage and drives the power FET into its saturation region, which switches the output into a constant-current mode and holds the current constant while varying the voltage on the load.

## Thermal Sense

The TPS206x implements a thermal sensing to monitor the operating temperature of the power distribution switch. In an overcurrent or short-circuit condition the junction temperature rises. When the die temperature rises to approximately 140°C due to overcurrent conditions, the internal thermal sense circuitry turns off the switch, thus preventing the device from damage. Hysteresis is built into the thermal sense, and after the device has cooled approximately 10 degrees, the switch turns back on. The switch continues to cycle off and on until the fault is removed. The open-drain false reporting output ( $\overline{OCx}$ ) is asserted (active low) when an overtemperature shutdown or overcurrent occurs.

## Undervoltage Lockout

A voltage sense circuit monitors the input voltage. When the input voltage is below approximately 2 V, a control signal turns off the power switch.

## REVISION HISTORY

Changes from Original (December 2003) to Revision A	Page
• Added devices to the data sheet- TPS2063, TPS2065, TPS2066, TPS2067 .....	1
• Added the General Switch Catalog .....	1
Changes from Revision A (July 2004) to Revision B	Page
• Changed Features Bullet From: UL Pending To: UL Listed - File No. E169910 .....	1
• Changed Electrical Characteristics - CURRENT LIMIT information. ....	4
Changes from Revision C (January 2006) to Revision D	Page
• Changed ORDERING INFORMATION table .....	2
Changes from Revision D (February 2007) to Revision E	Page
• Changed General Switch Catalog information. ....	1
Changes from Revision E (September 2007) to Revision F	Page
• Added the DBV-5 package. ....	1
• Added the DBV-5 package option. ....	1
• Added the DBV-5 package option to the Dissipation Ratings table. ....	3
• Changed Thermal Sense paragraph: From: Once the die temperature rises to approximately 140°C To: Once the die temperature rises above a minimum of 135°C .....	17

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**Changes from Revision F (April 2008) to Revision G** **Page**

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- Changed DBV-5 to Product Preview. .... 1
- 

**Changes from Revision G (July 2008) to Revision H** **Page**

---

- Deleted Product Preview from the DBV package ..... 1
  - Changed TPS2061DBV status From Preview to Active ..... 2
  - Changed TPS2065DBV status From Preview to Active ..... 2
- 

**Changes from Revision H (December 2008) to Revision I** **Page**

---

- Changed the ESD statement ..... 2
  - Deleted temp range of 0°C to 70°C from the Available Option table. .... 2
  - Added Note to the Available Options table - The printed circuit board layout is important for control of temperature rise when operated at high ambient temperatures ..... 2
  - Deleted temp range of 0°C to 70°C from the Ordering Information table. .... 2
  - Added Note to the Ordering Information table - The printed circuit board layout is important for control of temperature rise when operated at high ambient temperatures ..... 2
  - Changed the Abs Max Ratings table - Operating virtual junction temperature range From: -40°C to 125°C To: -40°C to 150°C ..... 3
  - Deleted Storage temperature range,  $T_{stg}$  from the Abs Max Ratings table ..... 3
  - Deleted MIL-STD-883C reference from ESD in the Abs Max table ..... 3
  - Added 3 table notes to the Dissipation Ratings table. .... 3
  - Added Addition values for the DBV-5 option in the Dissipation Ratings table. .... 3
  - Deleted Note - Not tested in production, specified by design from  $r_{DS(on)}$  in the Electrical Characteristics table. .... 3
  - Deleted Note - Not tested in production, specified by design from  $t_r$  in the Electrical Characteristics table. .... 3
  - Deleted Note - Not tested in production, specified by design from  $t_f$  in the Electrical Characteristics table. .... 3
  - Added text to the POWER DISSIPATION section - The thermal resistance,  $R_{\theta JA}$  ..... 17
-



**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS2061D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2061	<a href="#">Samples</a>
TPS2061DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2061	<a href="#">Samples</a>
TPS2061DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	2061	<a href="#">Samples</a>
TPS2061DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2061	<a href="#">Samples</a>
TPS2061DGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2061	<a href="#">Samples</a>
TPS2061DGNG4	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2061	<a href="#">Samples</a>
TPS2061DGNR	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2061	<a href="#">Samples</a>
TPS2061DGNRG4	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2061	<a href="#">Samples</a>
TPS2061DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2061	<a href="#">Samples</a>
TPS2061DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2061	<a href="#">Samples</a>
TPS2062D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2062	<a href="#">Samples</a>
TPS2062DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2062	<a href="#">Samples</a>
TPS2062DGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2062	<a href="#">Samples</a>
TPS2062DGNG4	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2062	<a href="#">Samples</a>
TPS2062DGNR	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2062	<a href="#">Samples</a>
TPS2062DGNRG4	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2062	<a href="#">Samples</a>
TPS2062DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2062	<a href="#">Samples</a>

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS2062DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2062	<a href="#">Samples</a>
TPS2063D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2063	<a href="#">Samples</a>
TPS2063DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2063	<a href="#">Samples</a>
TPS2063DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2063	<a href="#">Samples</a>
TPS2063DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2063	<a href="#">Samples</a>
TPS2065D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2065DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2065DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2065DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2065DGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2065DGNG4	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2065DGNR	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2065DGNG4	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2065DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2065DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2065	<a href="#">Samples</a>
TPS2066D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2066	<a href="#">Samples</a>
TPS2066DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2066	<a href="#">Samples</a>
TPS2066DGN	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2066	<a href="#">Samples</a>

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS2066DGNG4	ACTIVE	MSOP- PowerPAD	DGN	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2066	<a href="#">Samples</a>
TPS2066DGNR	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	2066	<a href="#">Samples</a>
TPS2066DGNRG4	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2066	<a href="#">Samples</a>
TPS2066DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2066	<a href="#">Samples</a>
TPS2066DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2066	<a href="#">Samples</a>
TPS2066ID	PREVIEW	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		
TPS2066IDR	PREVIEW	SOIC	D	8		TBD	Call TI	Call TI	-40 to 85		
TPS2067D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2067	<a href="#">Samples</a>
TPS2067DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2067	<a href="#">Samples</a>
TPS2067DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2067	<a href="#">Samples</a>
TPS2067DRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	2067	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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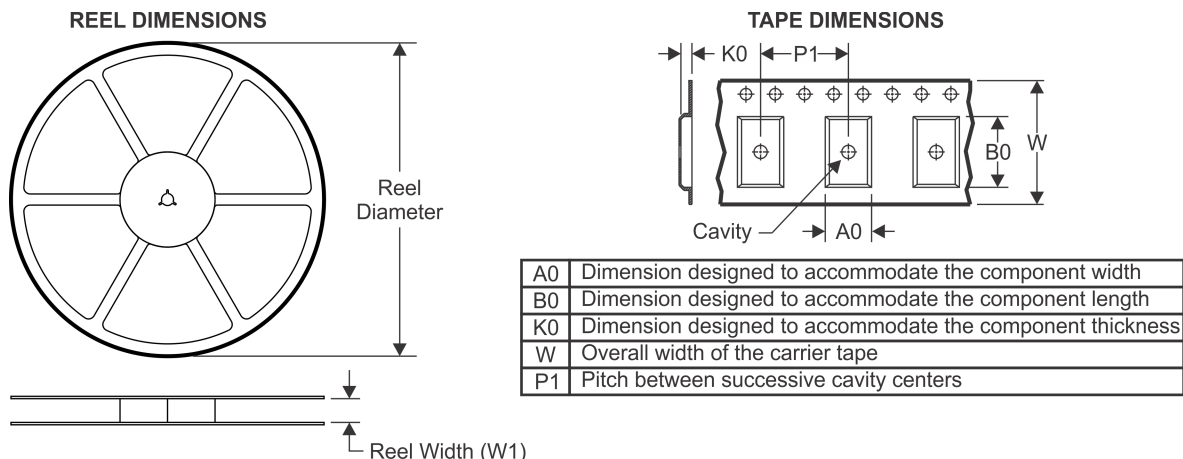
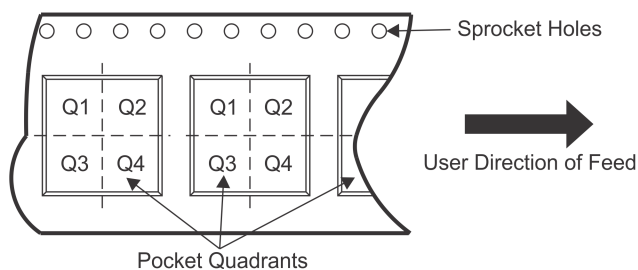
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TPS2062, TPS2065, TPS2066 :**

- Automotive: [TPS2062-Q1](#), [TPS2065-Q1](#), [TPS2066-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

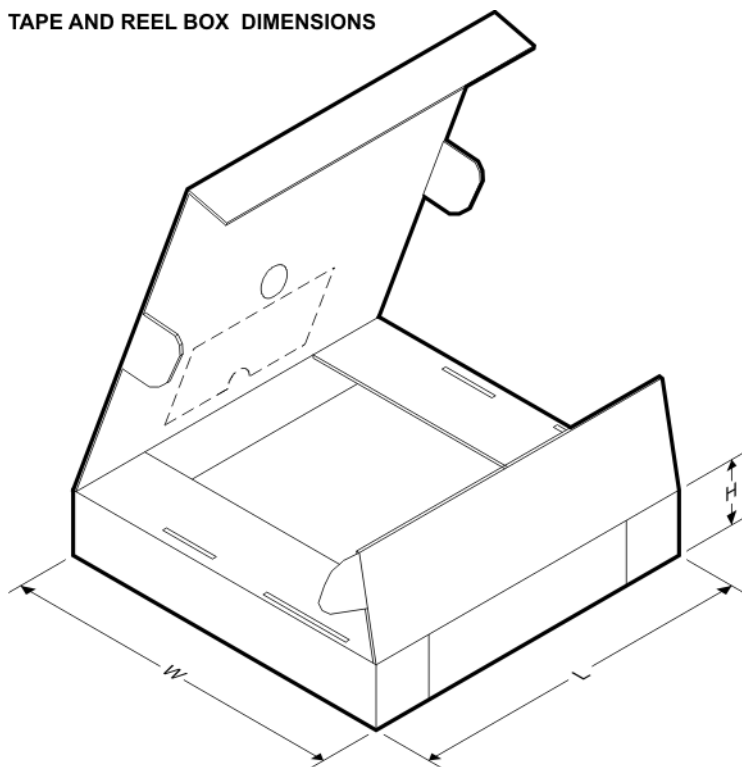
**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2061DBVR	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS2061DBVT	SOT-23	DBV	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS2061DGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS2061DGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2061DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2062DGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS2062DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2063DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TPS2065DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS2065DBVR	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS2065DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS2065DBVT	SOT-23	DBV	5	250	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS2065DGNR	MSOP-Power	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	PAD											
TPS2065DGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2065DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2066DGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
TPS2066DGNR	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS2066DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS2067DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

## TAPE AND REEL BOX DIMENSIONS



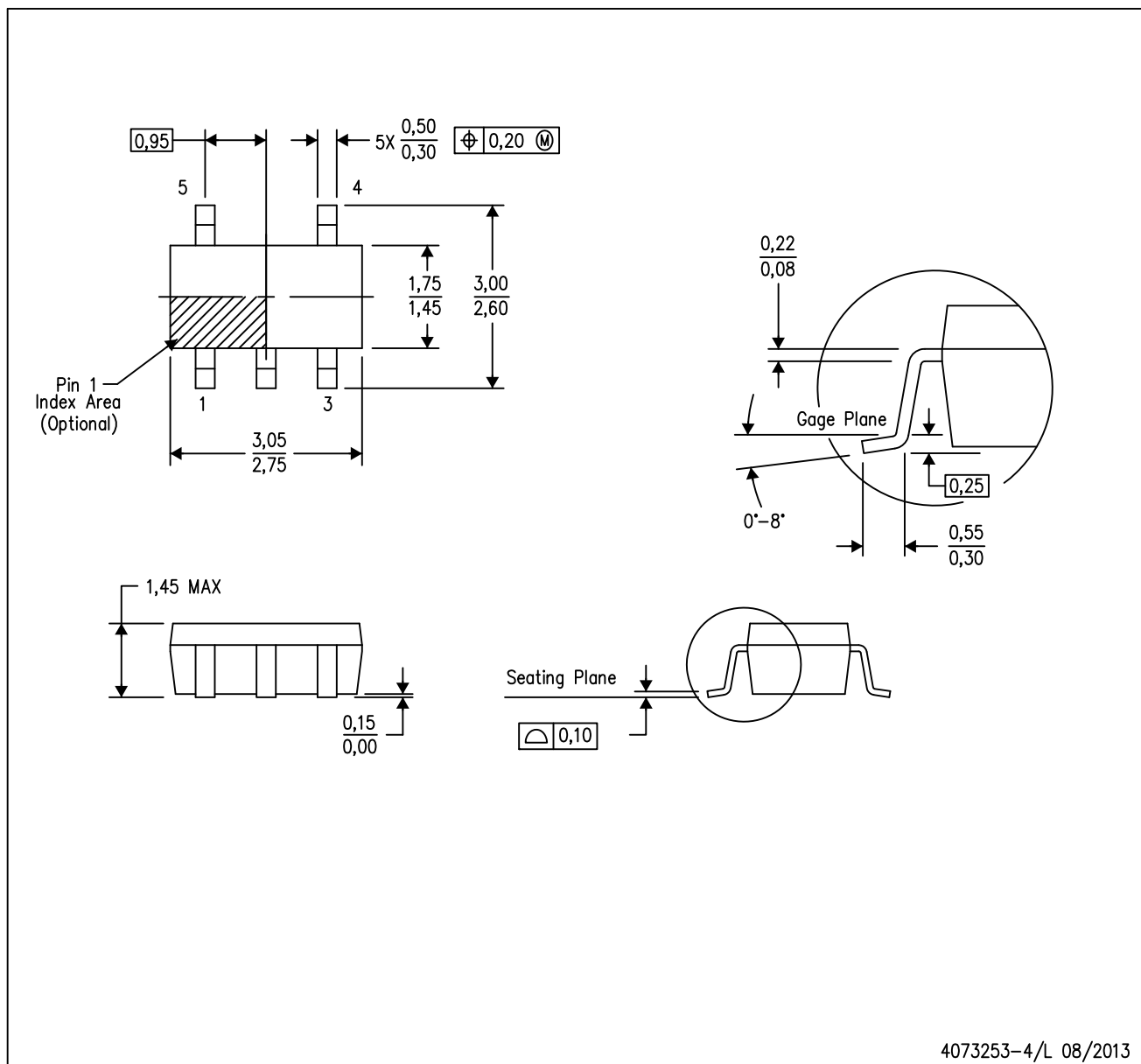
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2061DBVR	SOT-23	DBV	5	3000	203.0	203.0	35.0
TPS2061DBVT	SOT-23	DBV	5	250	203.0	203.0	35.0
TPS2061DGNR	MSOP-PowerPAD	DGN	8	2500	364.0	364.0	27.0
TPS2061DGNR	MSOP-PowerPAD	DGN	8	2500	346.0	346.0	35.0
TPS2061DR	SOIC	D	8	2500	340.5	338.1	20.6
TPS2062DGNR	MSOP-PowerPAD	DGN	8	2500	364.0	364.0	27.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2062DR	SOIC	D	8	2500	340.5	338.1	20.6
TPS2063DR	SOIC	D	16	2500	367.0	367.0	38.0
TPS2065DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS2065DBVR	SOT-23	DBV	5	3000	203.0	203.0	35.0
TPS2065DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS2065DBVT	SOT-23	DBV	5	250	203.0	203.0	35.0
TPS2065DGNR	MSOP-PowerPAD	DGN	8	2500	364.0	364.0	27.0
TPS2065DGNR	MSOP-PowerPAD	DGN	8	2500	346.0	346.0	35.0
TPS2065DR	SOIC	D	8	2500	340.5	338.1	20.6
TPS2066DGNR	MSOP-PowerPAD	DGN	8	2500	346.0	346.0	35.0
TPS2066DGNR	MSOP-PowerPAD	DGN	8	2500	364.0	364.0	27.0
TPS2066DR	SOIC	D	8	2500	340.5	338.1	20.6
TPS2067DR	SOIC	D	16	2500	333.2	345.9	28.6

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE

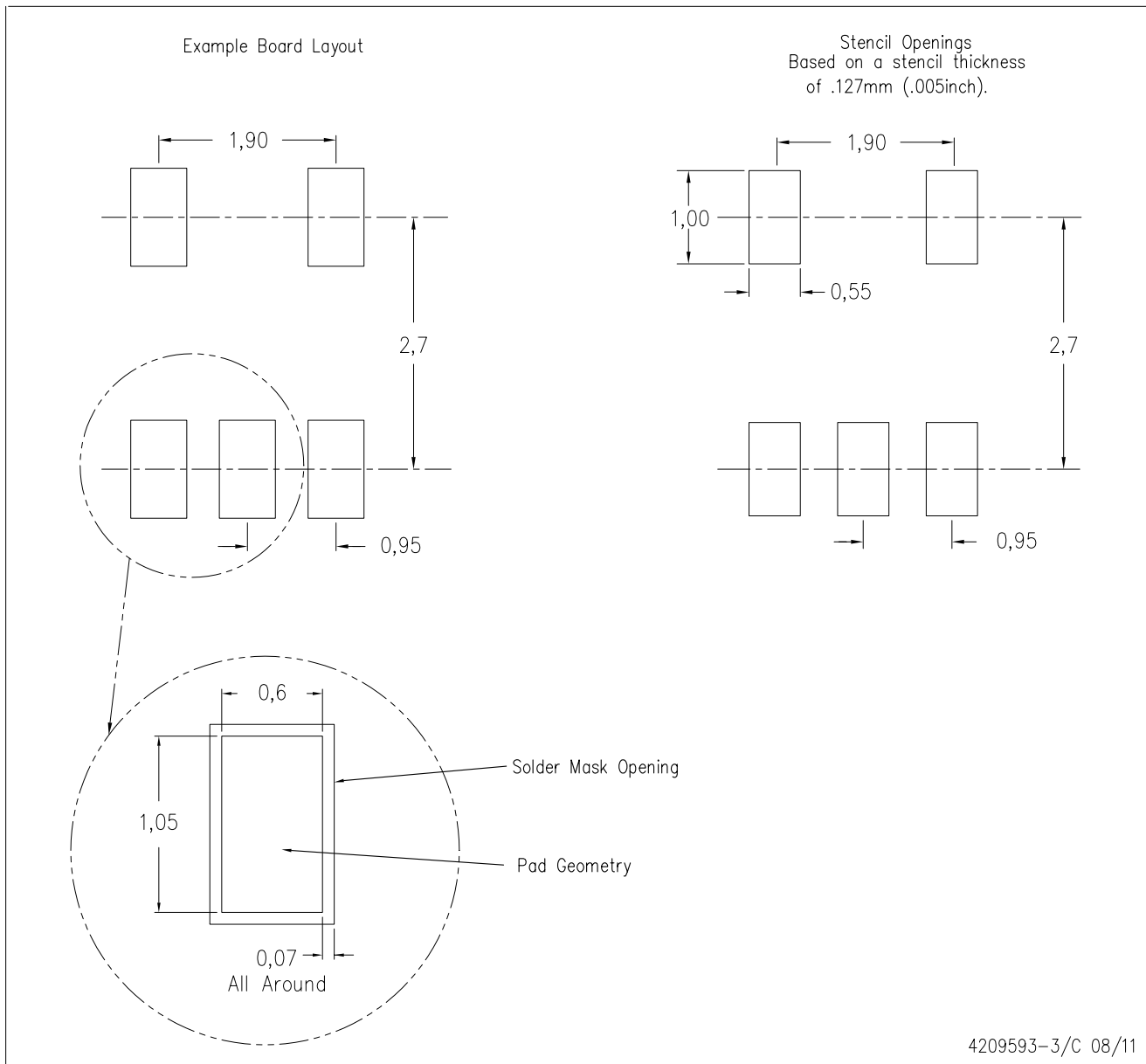


- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

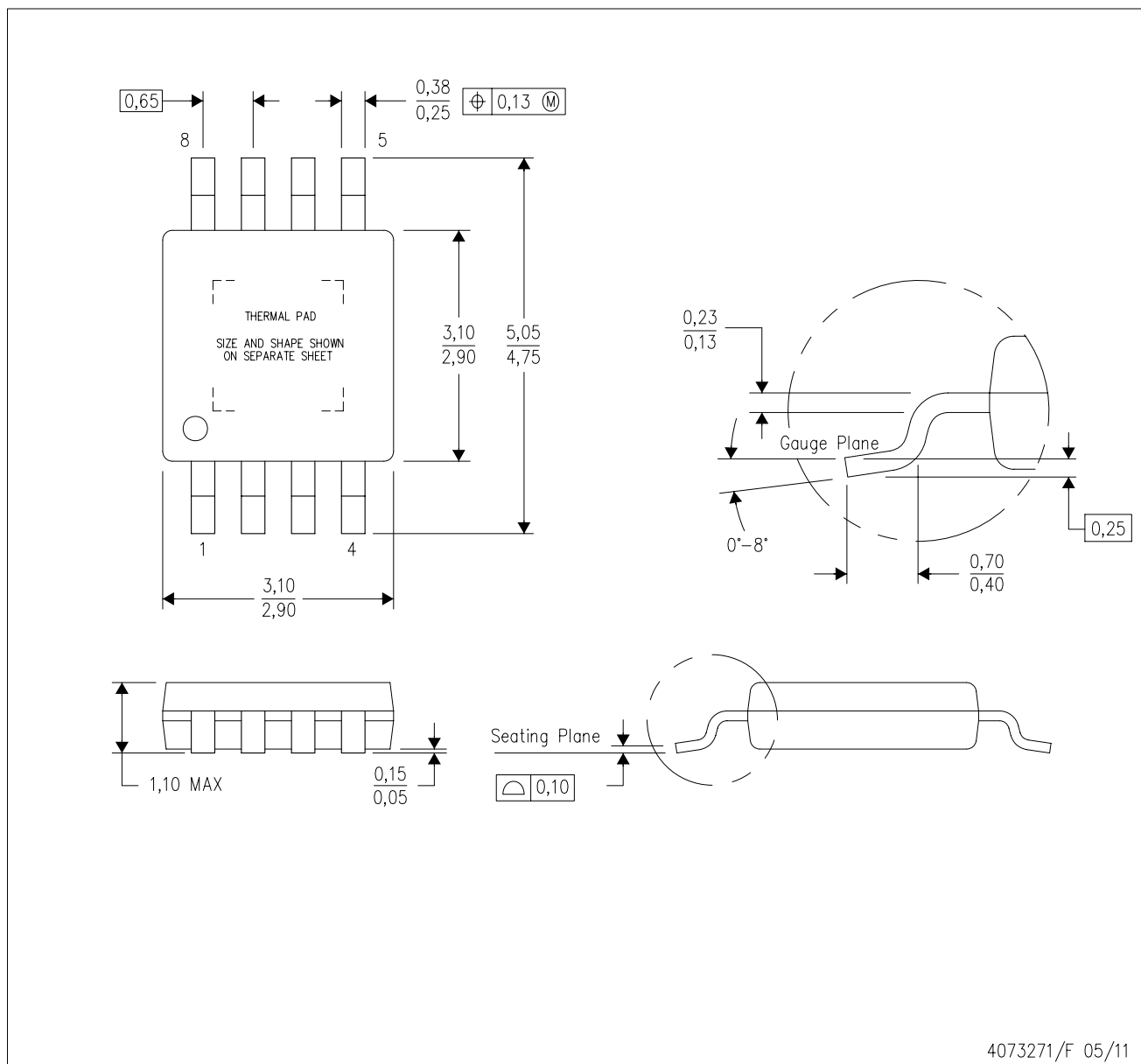
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - D. Publication IPC-7351 is recommended for alternate designs.
  - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

DGN (S-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
  - Falls within JEDEC MO-187 variation AA-T

PowerPAD is a trademark of Texas Instruments.

DGN (S-PDSO-G8)

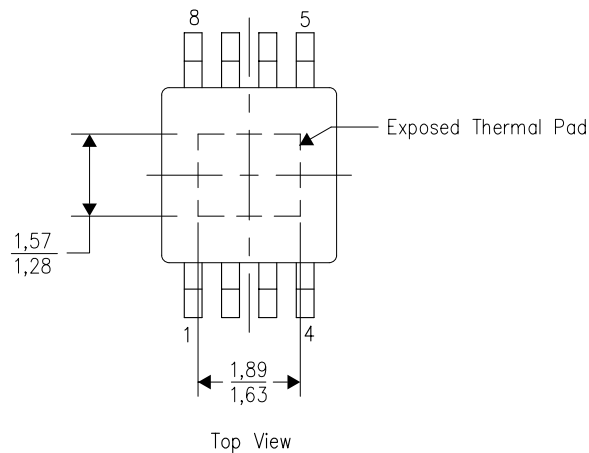
PowerPAD™ PLASTIC SMALL OUTLINE

## THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

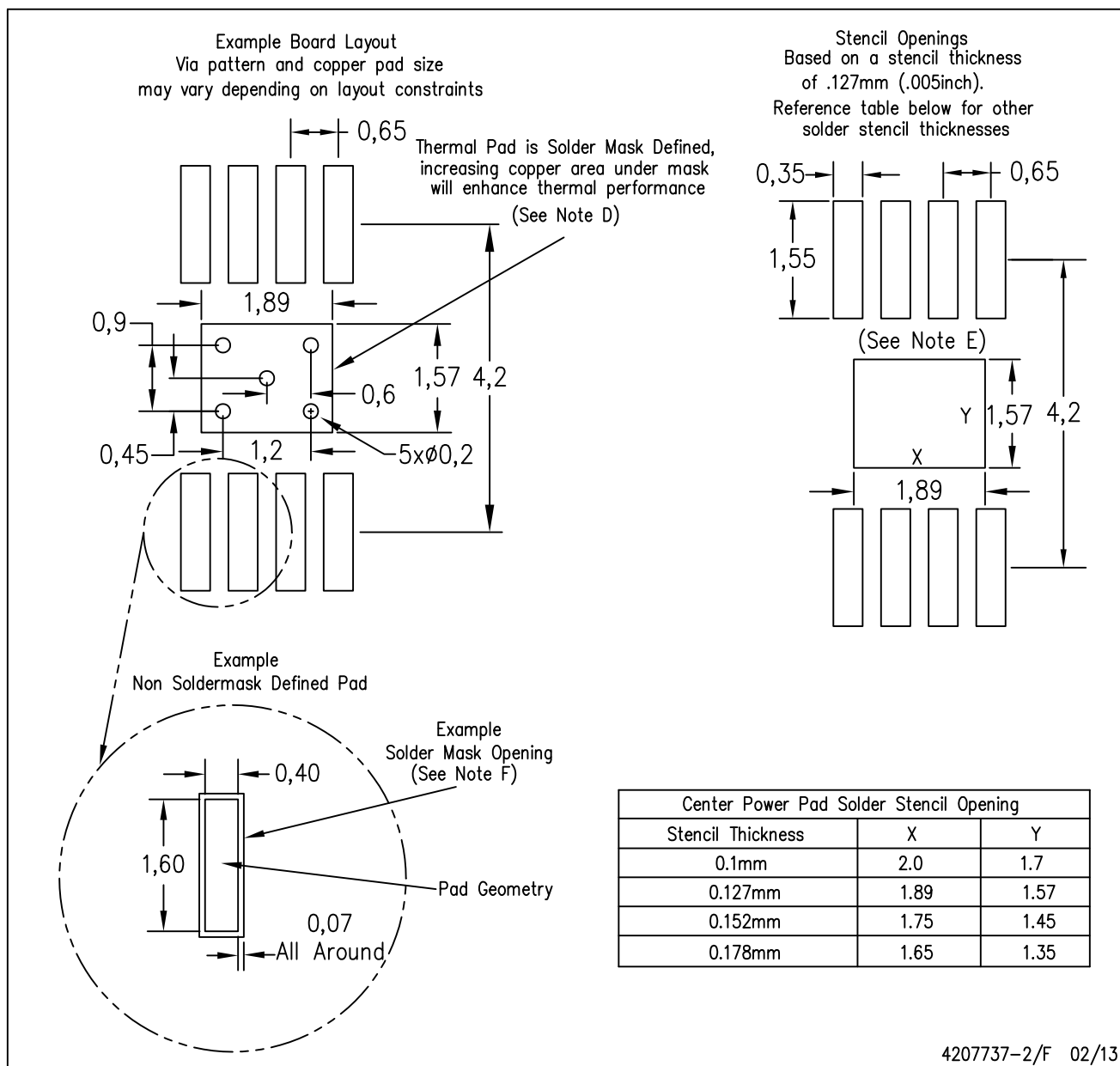
4206323-2/1 12/11

NOTE: All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments

DGN (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



4207737-2/F 02/13

- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
  - This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at [www.ti.com](http://www.ti.com) <<http://www.ti.com>>.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PowerPAD is a trademark of Texas Instruments

DGN (S-PDSO-G8)

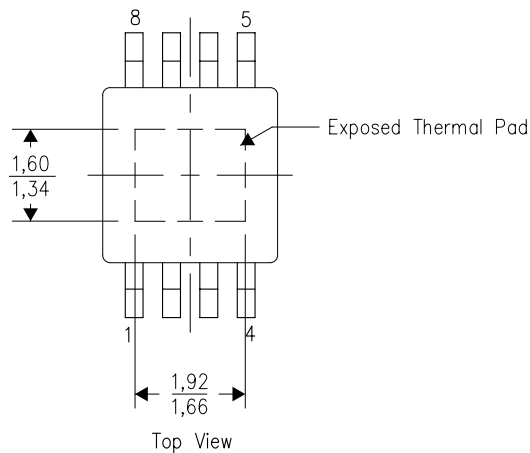
PowerPAD™ PLASTIC SMALL OUTLINE

## THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

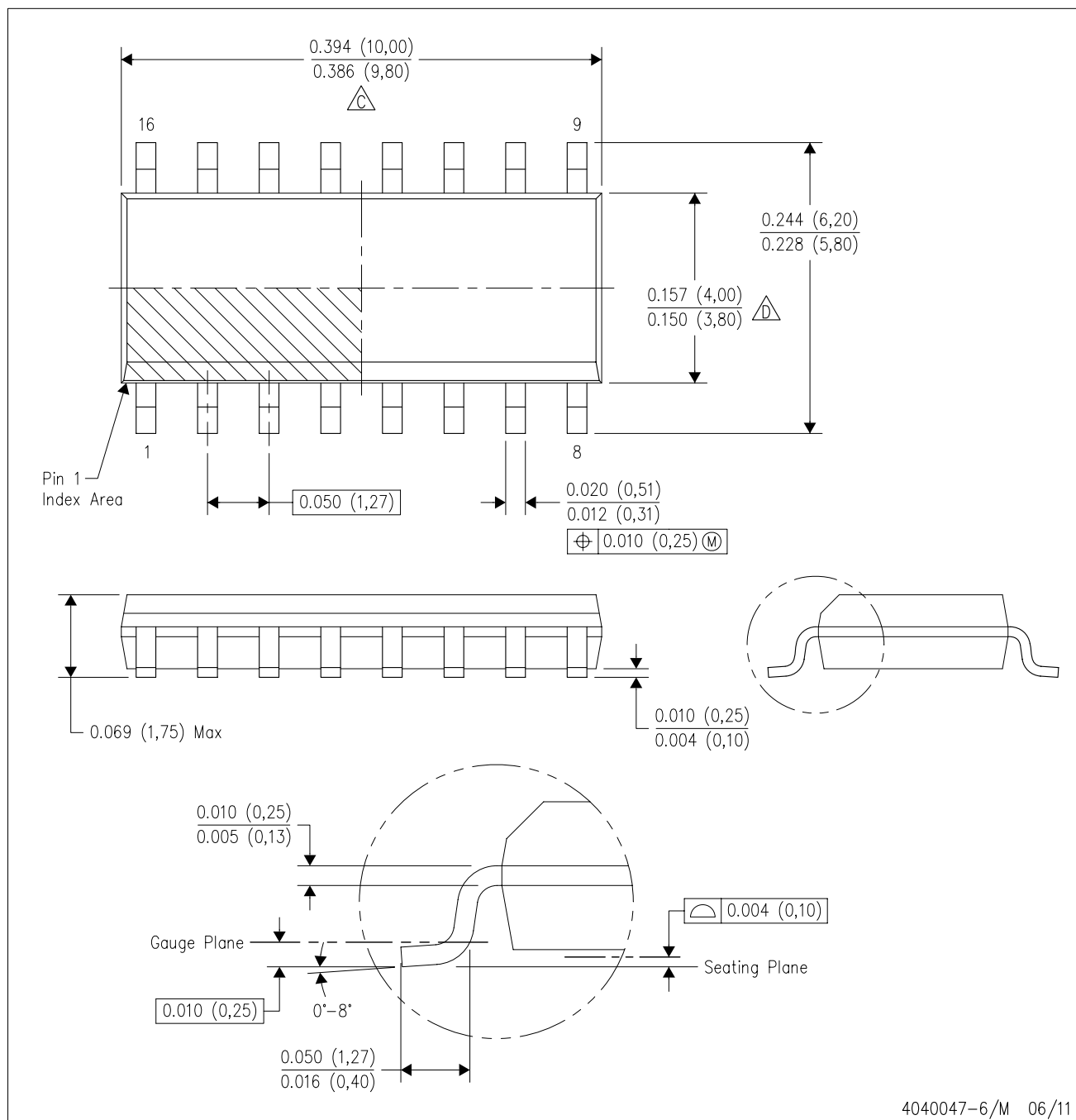
4206323-4/1 12/11

NOTE: All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE

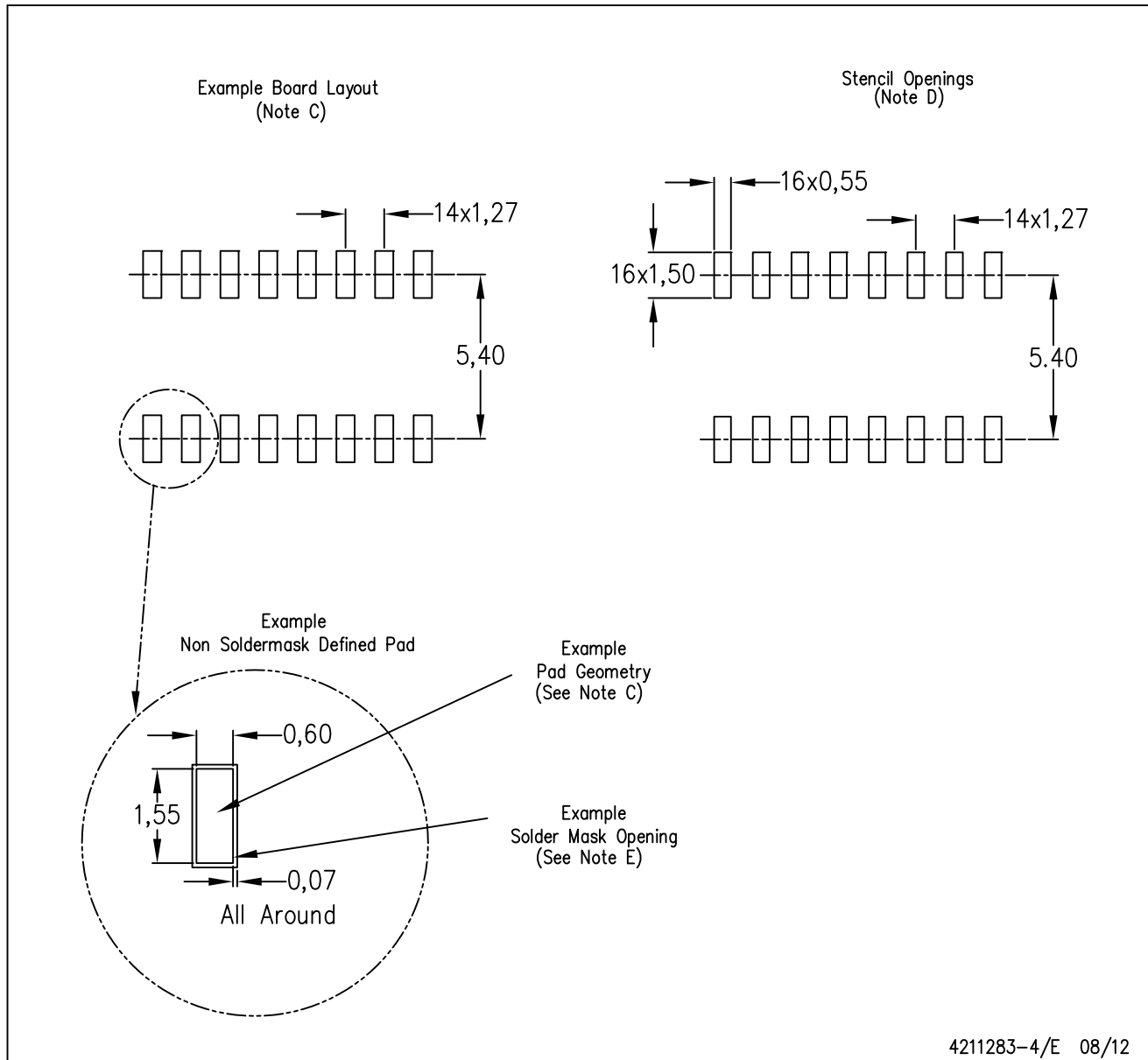


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

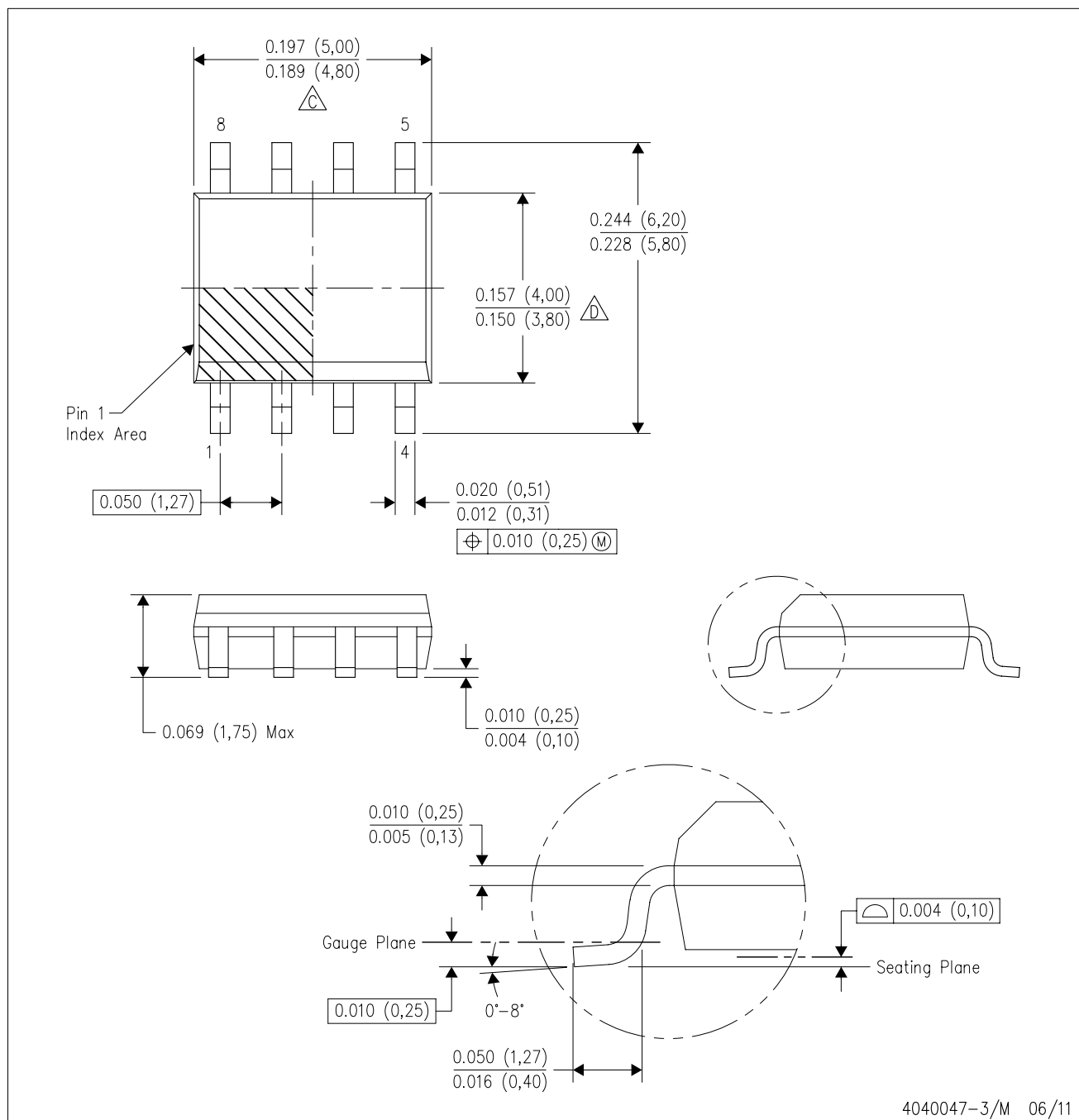
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE

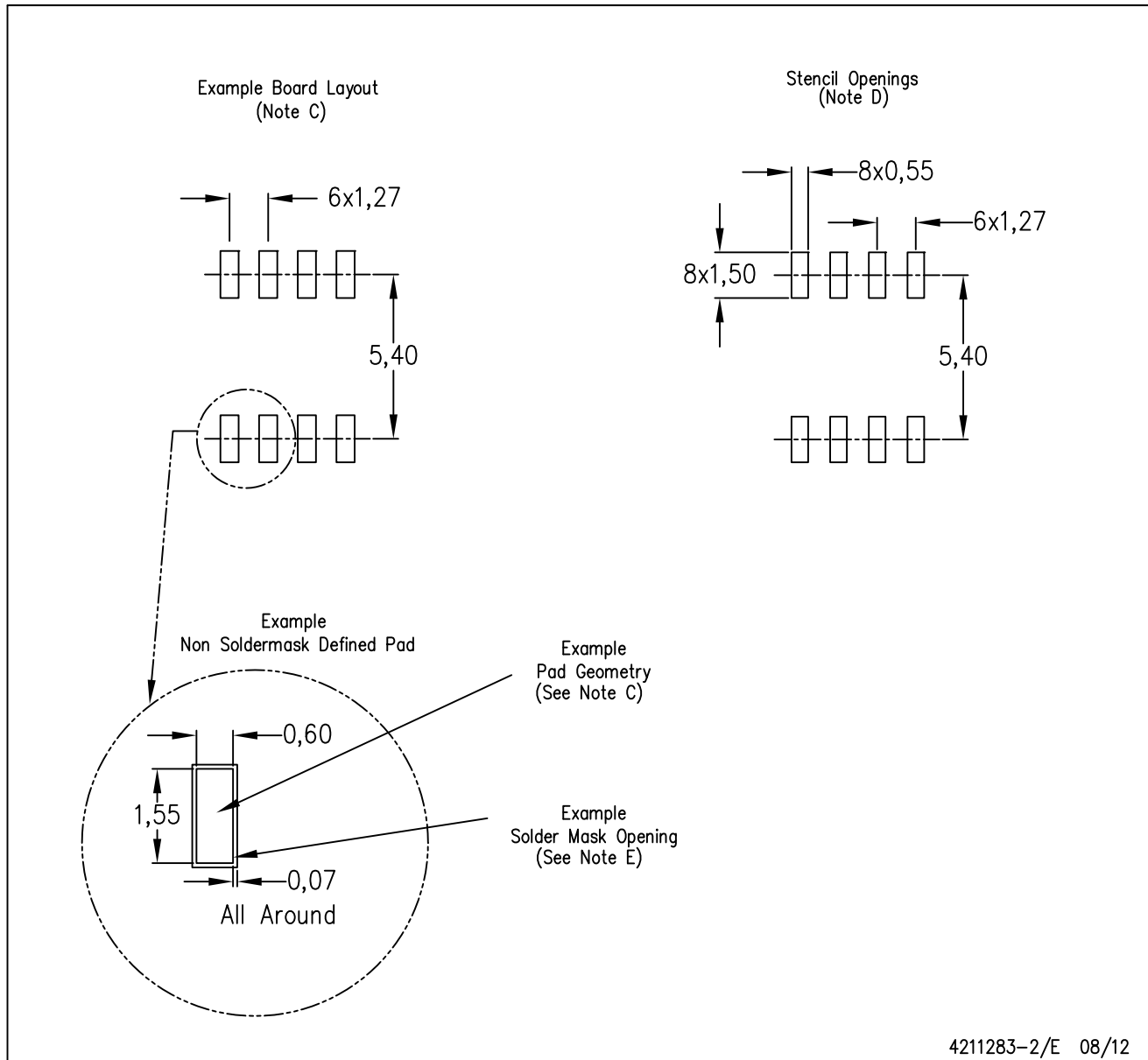


- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\triangle C$  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - $\triangle D$  Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

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Logic	<a href="http://logic.ti.com">logic.ti.com</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>
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RFID	<a href="http://www.ti-rfid.com">www.ti-rfid.com</a>
OMAP Applications Processors	<a href="http://www.ti.com/omap">www.ti.com/omap</a>
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### Applications

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